Preparation of SiCNFs Composite Anode by Electrophoretic Deposition (EPD)

Meng Yao

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Preparation of Si/CNFs Composite Anode by Electrophoretic Deposition (EPD)

Meng Yao

Dissertation submitted to Benjamin M. Statler College of Engineering and Mineral Resources at West Virginia University in partial fulfillment of the requirements for the degree of Doctor of Philosophy

In Mechanical Engineering

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Morgantown, West Virginia
2017

Keywords: silicon anode, composite film, surface modification, EPD, suspension stability

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ABSTRACT

Preparation of Si/CNFs Composite Anode by Electrophoretic Deposition (EPD)

Meng Yao

Recently, lithium ion batteries (LIBs) have been widely used in the field of portable electronic devices and electric vehicles due to high adaptability, high working voltage and low toxicity. However, traditional electrode materials have greatly limited the future of LIBs because of their low theoretical specific capacities; meanwhile, new electrode materials always need to be prepared by complicated and expensive methods, indicating the small probability of large-scale promotion. In this study, the Si/CNFs composite film anode without any binder by a simple and effective method - electrophoretic deposition (EPD) - is developed, which exhibits improved electrochemical properties.

This thesis is firstly focused on building a metastable/stable system for the multi-component (Si/CNFs) EPD. It’s observed that in the basic condition (pH9 – 10) or acidic condition (pH0.5), a suspension in ethanol consisting of surface-modified Si and CNFs can approximately keep stable for at least 0.5h, which can meet the minimum requirements for a successful deposition. Based on the dynamics analysis, a new “three-step growth theory” on the deposition process is proposed.

Then, this thesis is focused on preparing different composite films by EPD and improving their electrochemical performance via optimizing the component and microstructures. Three kinds of Si nanoparticles are used: Si, Si with hydroxyl groups (Si-OH) and Si with amino groups (Si-NH$_2$), while only one carbonaceous material is investigated: CNFs with carboxyl groups (CNFs-COOH). The possible factors on the film density, thickness and the microstructure have been studied, including the applied voltage, concentration, additives and after-treatment procedures. The results show that each dense composite film exhibits better performance than the tradition graphite anode. To be specific, the Si/CNFs-COOH film is obtained in ethanol by EPD at pH10, which has the specific capacity of 610 mAh/g after 100 cycles at 400 mA/g. The Si-OH/CNFs-COOH film with honeycomb structure is obtained in ethanol by EPD at pH10, which has the specific capacity of 510 mAh/g at 400 mA/g after 300 cycles. The Si-NH$_2$ /CNFs-COOH film is obtained by EPD at pH0.5, which has the specific capacity of 1020 mAh/g at 400 mA/g after 100 cycles.
ACKNOWLEDGEMENTS

First of all, I would like to thank my supervisor Dr. Xingbo Liu for the strong support of my Ph.D. research, for his patience, motivation, and immense knowledge.

Besides my supervisor, I would like to thank the rest of committee members: Dr. Xueyan Song, Dr. Xiaodong Shi, Dr. Hui Zhang, and Dr. Ismail Celik, for their insightful comments on my research. I would like to especially thank Dr. Hui Zhang for her selfless help at the beginning of my academic career. She taught me how to do real research.

Next, I would like to thank my teammates for the stimulating discussions and for the funs we have had in the past six years. In particular, I am grateful to Dr. Greg Collins, Dr. Wenyan Li and Dr. Jianhua Yan for helping me so much on building up a LIBs lab, experimental test and data analysis.

Last and the most importantly, I would like to thank my parents and my dear sister for their continuous support spiritually, especially when I made mistakes or was in troubles in my work. Their support is a huge source of my motivation.
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<td>LIB</td>
<td>Lithium ion battery</td>
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<tr>
<td>PE</td>
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<td>TX-100</td>
<td>Triton X-100</td>
</tr>
<tr>
<td>CNFs</td>
<td>Carbon nanofibers</td>
</tr>
<tr>
<td>SiNPs</td>
<td>Silicon nanoparticles</td>
</tr>
<tr>
<td>EPD</td>
<td>Electrophoretic deposition</td>
</tr>
<tr>
<td>ζ</td>
<td>Zeta potential</td>
</tr>
<tr>
<td>μ</td>
<td>Electrophoretic mobility</td>
</tr>
<tr>
<td>E</td>
<td>Electric field strength</td>
</tr>
<tr>
<td>C</td>
<td>Concentration</td>
</tr>
<tr>
<td>S</td>
<td>Surface area</td>
</tr>
<tr>
<td>ε</td>
<td>Dielectric permittivity of the solvent;</td>
</tr>
<tr>
<td>$k_B$</td>
<td>The Boltzmann constant</td>
</tr>
<tr>
<td>$n_c$</td>
<td>The bulk concentration of the ions</td>
</tr>
<tr>
<td>$\psi_d$</td>
<td>Stern plane potential</td>
</tr>
<tr>
<td>$\kappa^{-1}$</td>
<td>Debye length</td>
</tr>
<tr>
<td>$V_s$</td>
<td>The settling rate</td>
</tr>
<tr>
<td>$\Delta \rho$</td>
<td>The difference of density between the settled layer and the homogenous suspension</td>
</tr>
<tr>
<td>R</td>
<td>Particle diameter</td>
</tr>
<tr>
<td>η</td>
<td>Viscosity of the solvent</td>
</tr>
<tr>
<td>$f(\kappa \cdot a)$</td>
<td>Henry’s function</td>
</tr>
<tr>
<td>$RSH$</td>
<td>The relative sediment height</td>
</tr>
<tr>
<td>$C_{rd}$</td>
<td>The relative dynamic concentration of the homogeneous zone</td>
</tr>
</tbody>
</table>
\( t \)  Deposition time
\( Y \)  The Yield
\( I \)  Current
\( \Lambda \)  Conductivity
\( A \)  Correction coefficient on the electric field
Chapter 1

INTRODUCTION

With the fast development of modern society, demand for energy is increased even more quickly than we can imagine. A large amount of non-renewable energy source such as petroleum, natural gas, and coal are consumed every day, accompanied by serious environmental problems, therefore, it has great value to develop new clean and renewable energy \(^1\).

In the past, chemical power sources, like lead acid battery, cadmium nickel battery, and nickel metal hydride battery, were widely used because of its high conversion efficiency, high adaptability and long lifetime. As an uprising star, lithium ion battery (LIB) \(^2\) has attracted more and more attention due to its high working voltage, high energy density, low self-discharge, no memory effect and low toxicity, which has broader prospects in the field of portable electronics and electric vehicles.

Recently, the major countries of the world have introduced a series of policies to support LIB research, even rising the development of new energy vehicles to central strategic level. Therefore, the requirements for LIB performance become higher and higher, especially in terms of energy density/specific capacity and cycle life. As an important part, the anode of LIB has become one of the hot topics in the world.
Chapter 2

LITERATURE REVIEW

2.1 Lithium ion battery

LIB research originates from lithium battery \[^3\]. Due to the most negative potential (~3.05 V vs. a standard hydrogen electrode) and the lowest density among metals (\(\rho = 0.53 \text{ g} \cdot \text{cm}^{-3}\)), lithium (Li) has been considered as a potential alternative energy source since non-aqueous electrolytes such as LiClO\(_4\) in propylene carbonate was found in 1950s \[^4\]. The first commercial lithium battery was made in the late 1960s, and different systems were subsequently exploited, such as Li/MoS\(_2\) \[^5\] and Li/Li\(_x\)MnO\(_2\) \[^6,7\]. Some lithium batteries like Li/MnO\(_2\) \[^7,8\] cell are still being used for medical implants and military applications today. However, there are two serious problems for Li anode: 1) highly branched Li structures, called dendrites, can be formed constantly on the anode surface during cycling. They finally can penetrate the separator and cause short circuit; 2) high reactivity between Li and electrolyte results in security risks of battery storage and transportation. For example, the first manufacturer of commercial secondary lithium batteries in the world - Moli Energy, went bankrupt in the late 1980s because of a slew of negative news involving fire accidents during cells assembly.

Lithium battery has experienced the arduous process of development, but is still far from people's expectation. Luckily, some Li-containing compounds (Li\(_y\)M\(_m\)Y\(_m\)) \[^9\] that allow Li\(^+\) to free insert into or extract from interstitial sites were found in the late 1970s and early 1980s, combining with carbonaceous anode material to fabricate the secondary LIB. The first successful commercial LIB consisting of LiCoO\(_2\) cathode and soft carbon anode was made by Sony Corporation in 1991.

Generally, LIBs are made of four parts: cathode, anode, separator, and electrolyte.

LIB cathode materials \[^10\] mainly have four kinds of structure: LiMO\(_2\) (a layered structure, M=Ni, Co, Mn…), LiMPO\(_4\) (Olivine structure, M=Ni, Co, Mn, Fe…), LiMn\(_2\)O\(_4\) (spinel structure) and Li\(_3\)M\(_2\)(PO\(_4\))\(_3\) (NASCION structure, M=V, Fe…). In the current, the most common cathode materials are LiCoO\(_2\), LiNiO\(_2\), LiMn\(_2\)O\(_4\), LiNi\(_{1-x}\)Co\(_x\)Mn\(_2\)O\(_2\) and LiFePO\(_4\). Most of them have relatively low specific capacities (<200 mAh/g) and high working voltage of 3.3~4.0V (vs. Li\(^+\)/Li).
LIB anode materials \[^{10-12}\] mainly include carbonaceous materials (graphite, hard carbon, mesophase carbon micro beads…), TiO\(_2\), Sn, Si, transition metal oxides and transition metal sulfides. Among them, graphite is the most widely used anode with the specific capacity of 372 mAh/g due to its high stability and low cost.

LIB separator \[^{13}\] mainly has two types: polyethylene (PE) and polypropylene (PP) porous membranes, which are ionic conductive but electron insulated. It is placed between anode and cathode to prevent internal short circuit.

LIB electrolyte \[^{10, 14}\] provides a pathway for Li\(^+\) transport between cathode and anode, which should have high Li\(^+\) conductivity, low electron conductivity, wide electrochemical window, and high thermostability. Organic electrolyte is the first selection for current LIB that comprised of lithium salt (LiPF\(_6\), LiClO\(_4\), LiBOB, LiCF\(_3\)SO\(_3\)…) and organic solution (DMC, DEC, EC, EMC…). The most common combination is LiPF\(_6\) dissolved in the mixture of EC and DMC (1:1 v\%). Besides, aqueous electrolyte, solid electrolyte and additives like ionic liquid have also attracted much attention.

Fig. 2.1 \[^{10}\]: Schematic illustration of the Discharging/Charging mechanism of a LIB

Taking a typical LIB (Graphite/LiPF\(_6\)-EC-DEC/LiCoO\(_2\)) as an example, the working principle is showed in Fig. 2.1. Before electrochemical cycling, Li\(^+\) are located in the interstitial sites of LiCoO\(_2\). During the charging process, Li\(^+\) are released and move to the graphite. At the same time, graphite can get enough electrons from the external circuit to form Li\(_x\)C\(_n\) compound. During the discharging process, Li\(^+\) and electron transport are reversed. Intercalation mechanism can be described that Li ions "rock" from one side to the other. Hence, LIBs are also called "rocking-chair batteries". Under ideal conditions, Li\(^+\) insertion/extraction leads to the change of
interlayer spacing but remaining layer structure stable. The equations of this reversible process are listed as followed.

\[
\begin{align*}
\text{Cathode:} & \quad \text{LiCoO}_2 \leftrightarrow \text{Li}_{1+x}\text{CoO}_2 + x\text{Li}^+ + xe^- \\
\text{Anode:} & \quad \text{nC} + x\text{Li}^+ + xe^- \leftrightarrow \text{Li}_x\text{C}_n \\
\text{Overall:} & \quad \text{LiCoO}_2 + n\text{C} \leftrightarrow \text{Li}_x\text{C}_n + \text{Li}_{1-x}\text{CoO}_2
\end{align*}
\]

2.1

2.2

2.3

The capacity of LIB is determined by both cathode and anode materials. For example \cite{15}, if cathode material is fixed, the relationship between total capacity (C_T) and anode capacity (C_A) is shown in Fig. 2.2. The equation 2.4 is also listed. C_T is greatly improved as the increase of C_A from 100 – 1200 mAh/g. If C_A is over 1200 mAh/g, the improvement of C_T becomes negligible.

Fig. 2.2 \cite{15}: Total capacity of 18650 Li-ion cell as a function of anode capacity (C_A), including masses of other required internal components and case. Capacities of cathodes considered were 140 and 200 mAh/g.

\[
\text{Total cell (mAh/g)} = \frac{1}{\left(1/C_A\right) + \left(1/C_C\right) + \left(1/Q_M\right)}
\]

2.4\cite{15}

where:

\( C_A \) = the theoretical specific capacity of the cathode material;
\( C_C \) = the theoretical specific capacity of the anode material;
Q_M = the specific capacity of other cell components (electrolyte, separator, current collector, case, etc.).

2.2 LIB anode materials

Anode material plays a very important role in a LIB. An ideal anode should satisfy the following requirements:
1) Low voltage platform of Li insertion/extraction to achieve high output voltage of battery;
2) A large number of Li^+ per unit mass that can be reversibly taken off or embedded to achieve high specific capacity;
3) High structural stability and thermostability to achieve long cycle life;
4) High ionic and electron conductivity to achieve good rate performance;
5) No chemical reaction with electrolyte occurs to achieve high-level safety;
6) Low cost and low toxicity.

Fig. 2.3 [16]: A schematic representation of the different reaction mechanisms observed in electrode materials for lithium batteries. Black circles: voids in the crystal structure, blue circles: metal, yellow circles: lithium.

Anode materials can be divided into three groups on basis of Li insertion/extraction mechanism [16], as shown in Fig.2.3.

Embedded type mainly includes carbonaceous materials, TiO_2 and Li_4Ti_5O_12, which obeys intercalation mechanism (Eq.2.3). Some materials such as Si, Ge, Sn and Sb, called
alloying anode, obeying the alloying mechanism. During electrochemical cycles, Li-alloys can be formed reversibly (Eq.2.5). Because the lithiation/delithiation process is not restricted by interlayer spacing of layer structure, much higher specific capacities can be obtained, especially for Si. The third type, conversion anode, mainly includes transition metal oxides, sulfides, nitrides, and phosphide. Li insertion/extraction is achieved by the conversion reaction, as shown in Eq.2.6.

\[
xLi^+ + xe^- + M = Li_xM \\
M_aY_b + bLi = aM + bLi_aY
\]

### 2.3 Si anode material

As the second most abundant element on earth, Si has the highest specific capacity (4200 mAh/g for Li<sub>4.4</sub>Si, as shown in Table 2.1), which is considered as the most promising anode in the future.

<table>
<thead>
<tr>
<th>Anode</th>
<th>Li</th>
<th>C</th>
<th>Si</th>
<th>Li&lt;sub&gt;4&lt;/sub&gt;Ti&lt;sub&gt;5&lt;/sub&gt;O&lt;sub&gt;12&lt;/sub&gt;</th>
<th>Sn</th>
</tr>
</thead>
<tbody>
<tr>
<td>Density (g/cm)</td>
<td>0.53</td>
<td>2.25</td>
<td><strong>2.33</strong></td>
<td>3.5</td>
<td>7.29</td>
</tr>
<tr>
<td>Lithiated phase</td>
<td>Li</td>
<td>LiC&lt;sub&gt;6&lt;/sub&gt;</td>
<td>Li&lt;sub&gt;4.4&lt;/sub&gt;Si</td>
<td>Li&lt;sub&gt;4&lt;/sub&gt;Ti&lt;sub&gt;5&lt;/sub&gt;O&lt;sub&gt;12&lt;/sub&gt;</td>
<td>Li&lt;sub&gt;4.4&lt;/sub&gt;Sn</td>
</tr>
<tr>
<td>Theoretical specific capacity (mAh/g)</td>
<td>3862</td>
<td>372</td>
<td><strong>4200</strong></td>
<td>175</td>
<td>994</td>
</tr>
<tr>
<td>Volume change (%)</td>
<td>100</td>
<td>12</td>
<td><strong>300</strong></td>
<td>--</td>
<td>260</td>
</tr>
<tr>
<td>Potential vs Li (~V)</td>
<td>0</td>
<td>0.05</td>
<td><strong>0.4</strong></td>
<td>1.6</td>
<td>0.6</td>
</tr>
</tbody>
</table>

However, there are three major disadvantages for Si anode.

1) Poor conductivity (6.7×10<sup>-4</sup>S/cm), indicating poor rate performance;
2) Huge volume change (up to 320%) during lithiation/delithiation, which causes the fracture of Si particles and weakens the contact between anode and current collector. Finally, electrode structure will be totally damaged, accompanied by rapidly decreased capacity and bad cycle life;
3) Poor compatibility between Si and LiPF<sub>6</sub>. Si can react with HF (one of the decomposition products of LiPF<sub>6</sub>) to form solid electrolyte interface film (SEI). More
Si will be exposed to the surface because of huge volume change during cycling, making this reaction further aggravated. Therefore, SEI will become unstable, indicating low coulombic efficiency and worse cycling performance. These disadvantages have severely limited the application of Si in the field of high energy-density and high power-density LIBs.

2.3.1 Mechanism of (de)lithiation of Si

As described in Part 2.2, Si anode is one of alloying anode materials. Its (de)lithiation mechanism, especially during the first two cycles, has been investigated for a long time.

Fig. 2.4 [17]: Si electrochemical lithiation and delithiation curve at room temperature and high temperature. Black line: theoretical voltage curve at 450 °C. Red and green line: lithiation and delithiation of crystalline Si at room temperature, respectively.

At high temperature, Si has the highest theoretical specific capacity of 4200 mAh/g. Four phases [17] can be formed during the alloying of Li-Si: Li_{1.71}Si (332 mV), Li_{2.33}Si (288 mV), Li_{3.75}Si (158 mV) and Li_{4.4}Si (44 mV), and alloying/de-alloying process is reversible, as shown in Fig. 2.4. However, at room temperature, each Si atom can react with some Li atoms, usually no more than 3.75. The corresponding theoretical capacity decreases to 3579 mAh/g.

Fig. 2.5 is the typical voltage profiles of Si anodes for the first two cycles at room temperature.
Galvanostatic curve recorded on arrays of crystalline Si NWs grown by Cu-catalyzed VLS and mounted in half-cell geometry with a Li counter electrode.

During the first lithiation process (discharging), crystalline Si (c-Si) is gradually transformed into amorphous phase, forming amorphous intermetallic compounds (a-Li\textsubscript{x}Si) such as Li\textsubscript{12}Si\textsubscript{7}, Li\textsubscript{7}Si\textsubscript{3}, and Li\textsubscript{13}Si\textsubscript{4}\textsuperscript{[19]}. A long and even plateau of the lithiation curve (Fig. 2.5a) represents a two-phase equilibrium between c-Si and a-Li\textsubscript{x}Si \textsuperscript{[18]}. The lithiation voltage plateau has been influenced by the ingredient of Si. For n-doped Si \textsuperscript{[20]}, lithiation starts around 90 mV, while it starts at 680 mV for p-doped Si. At the end of this plateau, all the c-Si has disappeared and the voltage has dropped to around 60 mV. There are some controversies about the final state of a-Li\textsubscript{x}Si when the voltage is further decreased (< 60 mV). Li et al. \textsuperscript{[21]} thought Li\textsubscript{15±δ}Si\textsubscript{4} would be formed with a maximum capacity of 3800 mAh/g, still less than 4200 mAh/g.

During the first delithiation process (charging), Li\textsubscript{15±δ}Si\textsubscript{4} is gradually replaced by an amorphous phase, a-Li\textsubscript{y}Si (y is commonly equal to 2 \textsuperscript{[21]}), which corresponds to a voltage plateau of 345 mV. When all the Li\textsubscript{15±δ}Si\textsubscript{4} disappears, Li will be extracted from a-Li\textsubscript{y}Si at a voltage plateau of 485 mV. In the end, amorphous Si is re-formed (a-Si\textsubscript{r}). It’s noticed that a-Si\textsubscript{r} is different from commercial amorphous Si (a-Si\textsubscript{c}) without cycling. A single Si atom in a-Si\textsubscript{c} has tetrahedral structure with some small distortions, while the structure of a-Si\textsubscript{r} becomes more unordered and has wider distribution of lattice sizes.

Starting the 2\textsuperscript{nd} cycle, (de)lithiation mechanisms become similar. The 2\textsuperscript{nd} lithiation process can be divided into two stages. The first stage is the breakage of Si-Si bond in a-Si\textsubscript{r}, accompanied by the formation of a-Li\textsubscript{2.3}Si at a plateau of 200 mV. The second stage is the transformation from Li\textsubscript{2.3}Si to Li\textsubscript{15±δ}Si\textsubscript{4} after all the a-Si\textsubscript{r} is gone. In theory, a-Si\textsubscript{r} should not be
existed at the end of lithiation process, but Baris Key et al.\textsuperscript{[22]} still found some Si-Si bonds even if the voltage drops to 0 mV, possibly caused by volume effect. Huge volume change during cycling leads to bad connection between a-Si and current collector. Therefore, less Si atoms are involved into alloying reaction with the increase of cycles. There is no obvious difference between the first delithiation process and the following ones. But similarly, not all the Li can be extracted from Li\textsubscript{15+δ}Si\textsubscript{4}, finally leading to the decrease of the specific capacity of anode.

The reaction equations on (de)lithiation mechanism during the first two cycles are listed as follows.

\begin{align*}
\text{First lithiation:} & \quad c\text{-Si} \rightarrow a\cdot \text{Li}_x\text{Si} \rightarrow \text{Li}_{15+\delta}\text{Si}_4. \\
\text{First delithiation:} & \quad a\cdot \text{Li}_{15+\delta}\text{Si}_4 \xrightarrow{345mV} a\cdot \text{Li}_x\text{Si} \xrightarrow{485mV} a\cdot \text{Si}_r. \\
\text{Second lithiation:} & \quad a\cdot \text{Si} \xrightarrow{200mV} a\cdot \text{Li}_3\text{Si} \rightarrow a\cdot \text{Li}_{15+\delta}\text{Si}_4. \\
\text{Second delithiation:} & \quad a\cdot \text{Li}_{15+\delta}\text{Si}_4 \xrightarrow{345mV} a\cdot \text{Li}_x\text{Si} \xrightarrow{485mV} a\cdot \text{Si}_r. 
\end{align*}

In most cases, a-Li\textsubscript{x}Si has been analyzed by using X-ray Diffraction (XRD), Nuclear Magnetic Resonance (NMR) and Transmission Electron Microscopy (TEM). It’s still a challenge of monitoring the elements and structural changes in real-time in the process of Si phase transition because of the extreme sensitivity of a-Li\textsubscript{x}Si to the environment. Recently, some in-situ measurement techniques have been developed, which can provide more accurate information. For example, Etienne Radvanyi et al.\textsuperscript{[23]} used in-situ Auger Electron Spectroscopy (AES) to confirm the formation of a Li\textsubscript{3.1}Si shell surrounding Si core as lithiation process starts. Liu et al.\textsuperscript{[24]} studied the breakage of Si-Si and recombination of Li-Si at the a-Li\textsubscript{3.5}Si-c-Si interface by using in-situ TEM and proposed lithiation process is controlled by Li\textsuperscript{+} migration of the interface.

Many people have been interested in the orientation of lithiation during the first cycle because most volume expansion happens during the initial crystalline-to-amorphous transformation than during the following cycles, helping better understand volume effect. For example, Lee et al.\textsuperscript{[25]} fabricated c-Si nanopillars with three different axial orientations (\textit{<100>}, \textit{<110>}, and \textit{<111>}). After the 1\textsuperscript{st} lithiation, the average volume expansion ratios of pillars with \textit{<100>}, \textit{<110>}, and \textit{<111>} axial orientations were 242.7\%, 270.8\%, and 263.8\%, respectively, as shown in Fig.1.6, meaning the expansion prefers to take place at the (110) top surface planes. Beaulieu et al.\textsuperscript{[26]} studied the volume change of thin a-Si films by in situ Atomic Force
Microscopy (AFM). The maximum volume change is about 300%, little from the lateral direction due to physical constraint of the substrate.

Fig.2.6 [25]: a-c) In situ TEM images of the electrochemical lithiation of a Si nanoparticle with an initial diameter of about 160 nm. a) Pristine nanoparticle; b) The same particle after 21 cycles of lithiation; c) Further lithiation; d-f) SEM images of Si nanopillars with three different axial orientations ( < 100 >, < 110 >, and < 111 >) after partial lithiation and subsequent removal of the lithiated phase to expose the crystalline cores.

2.3.2 Development of Si-based anode materials

Silicon has been considered as one of the most promising substitutes for tradition graphite anode due to its highest specific capacity in the nature. However, poor conductivity, huge volume change during lithiation/delithiation and unstable SEI have greatly limited its development. For example [27], capacity loss of a commercial Si anode can be up to 50% after the 1st cycle and the cycle life is no more than 10, making the industrialization impossible.

To solve these problems and improve electrochemical performance of Si anode, the key is increasing anode conductivity and prohibiting Si volume effect to maintain structural stability and good contact between anode and current collect during cycles. Nowadays, various approaches have been proposed, such as fabricating Si nanostructures, introducing carbonaceous
framework, synthesizing Si alloy composite and so on. They can be mainly divided into two groups: 1) improvement of pure Si system; 2) formation of composite system. Besides, electrolyte also plays a very important role in the battery performance. For example, some additives like fluoroethylene carbonate (FEC) \(^{[28]}\) can effectively improve the stability of Si microstructure and prolong battery life. It makes no sense to compare different anode materials if using different electrolytes. Therefore, all the electrolytes used in the literatures here except specific mention are same: LiPF\(_6\) (1.0 M) dissolved in ethylene carbonate and diethyl carbonate (EC/DEC, 1:1 v\%).

**Pure Si anode material**

1) Amorphous Si

   Compared with crystalline Si, amorphous Si (a-Si) has lower activation energy barrier that can reduce strain force of the structure to relieve the volume change during cycling. For example, Farmakis F. et al. \(^{[29]}\) prepared the a-Si anode with the micro-grain structure by DC sputtering on Cu foil. This anode exhibits very stable specific capacity up to 2000 mAh/g after 50 cycles at 1A/g.

   Generally, most a-Si anodes only exhibit good cycle performance with not much high specific capacity at low current rate because of its limited inhibition of volume effect. What’s worse, it’s difficult to improve the cycle life further via adjusting the microstructure or lithiation orientation. Therefore, amorphous Si is not a research hotspot today.

2) Nano-Si

   Nano-Si has higher specific surface area and more grain boundaries than bulk Si, which is beneficial for Li\(^+\) transport at the interface, leading to better rate performance. Besides, Si nanoparticles can use space resources more effectively than bulk ones, meaning apparent volume change during lithiation/delithiation will be decreased. For example, Liang J.W. et al. \(^{[30]}\) hydrothermally prepared porous Si nanospheres without any carbon coating in an autoclave at 180°C, which delivers a great cycling stability of 950 mAh/g at 3.6 A/g during 500 cycles.

   At present, the research of nano-Si anode mainly focused on the design of microstructure and morphology, such as Si nanowires \(^{[31]}\), Si nanotubes \(^{[32]}\), Si nanospheres \(^{[30]}\) and other porous Si structures \(^{[33]}\).

   As a typical 1D nanomaterial, Si nanowires and nanotubes exhibit improved electrochemical performance due to quick Li\(^+\) transport along with 1D direction without interface
barriers. For example, Cho J.H. et al.\textsuperscript{[31]} used a special template (anodized aluminum oxide) to obtain the Si nanowire anode on the Cu foil, which can effectively avoid the formation of the parasitic Si islands along with Si nanowires and exhibit high specific capacity of 1000 mAh/g over 1100 cycles at 1 A/g.

Although some nano-Si anode materials have relatively high capacity and long life, the expensive and complex preparation methods have limited their large-scale production.

3) Si film

A few Si film anodes also showed good cycling stability, especially those consisting of amorphous Si and nano-Si. For example, Demirkan M.T. et al.\textsuperscript{[34]} prepared Si films with the controllable thickness by magnetron sputtering at different Ar pressures. The good cycle performance can be only obtained when the film density is low (1.64 g/cm\textsuperscript{3}, similar to 30\% porosity). After 100 cycles, the specific capacity can be up to 650 mAh/g at 500 mAh/g.

The main problem of Si film anode is low unit loading. Because of the serious volume effect during cycles, it’s impossible to obtain a thick (>10μm) and dense film on the traditional Cu foil with long cycle life.

\textbf{Si/C composites}

Fabricating Si/C composites is a popular way to reduce irreversible capacity and prolong battery life. Carbonaceous materials such as porous carbon microsphere, graphite, carbon nanotubes/nanofiber (CNTs/CNFs), and graphene have been very attractive because of their softness and compliance, relatively low mass, good electronic conductivity, reasonable Li\textsuperscript{+} insertion ability, and small volume expansion. They cannot only improve the electrode’s conductivity, but also provide a flexible skeleton to buffer the huge volume change stress of Si and maintain the anode structure. Carbonaceous materials have much smaller specific capacities than Si that will decrease the total capacity of composite anode, but considering the limit of specific capacities of the current cathode materials, as mentioned in Part 2.1 (Fig.2.2), it’s acceptable to sacrifice a portion of Si capacity to improve integral stability.

Recently, people have prepared various Si/C composite anodes with specific morphologies by different methods such as high energy ball milling (HEBM), chemical vapor deposition (CVD), pyrolysis, chemical/physical etching, electrodeposition, electrospinning or multi-methods. Active material’s performance primarily depends on its microstructure, therefore, based on the structural features, Si/C composite anodes can be divided into four groups: Si/C
particles, including various hierarchical structures; Si/C co-axial structures; Si/C film; other structures.

1) Si/C particles

**Simple mixing type** People started the research on introducing carbonaceous materials with simple mixing or coating method in the early days. Much attention was paid to the uniformity of mixture and continuity of carbon coating, hardly fine structure design, as shown in Fig.2.7.

![SEM](https://via.placeholder.com/150)

**Fig.2.7:** SEM of typical morphology by a) ball milling\(^{[35]}\) or b) pyrolysis\(^{[36]}\) in the early years

The typical synthesis methods are (HE)BM, thermal vapor deposition (TVD) and CVD.

Ball milling method has many advantages, such as uniform distribution of Si, controllable unit particle size, and accurate Si/C ratio. Besides, it has great potential in industrialization because of low cost, simple operation and mild preparation conditions. Many people have synthesized Si/C composites by using this method. The electrochemical performance can be improved via increasing the amount of C and prolonging the grinding time to reduce particle size. For example, Yoshio M. et al.\(^{[37]}\) prepared Si/graphite anode with different weight ratios. They found the composite still has the capacity of 500 mAh/g after 80 cycles when the ratio of Si to graphite is 7:3.

Composite performance can be also influenced by the anode components, such as carbon source and additives. Zuo P.J. et al.\(^{[38]}\) prepared Si/graphite anode (1:4 w%) with the average size of 18 μm by ball milling for 20h under argon protection, which maintain a high capacity of 469 mAh/g after 40 cycles. They also used the same way to fabricate Si/Cu/graphite composite\(^{[39]}\). A new alloy phase (Cu\(_3\)Si) could be formed to further improve the composite conductivity.
Zhang Y. et al.\textsuperscript{[40]} introduced multi-walled carbon nanotubes (MWCNTs) into Si/graphite by using 12h ball milling. Si particles were embedded into the “lamellar structures” of flaked graphite, and then tightly wrapped by MWCNTs network. A reversible capacity of 584 mAh/g after 20 cycles was maintained. Wang G.X. et al.\textsuperscript{[41]} mixed smaller crystalline Si particles (80 nm) with MCMB (10 μm) and found MCMB framework remained spherical if grinding time is no more than 10h, which exhibit a capacity of 1066 mAh/g after 25 cycles.

However, the improvement of electrochemical performance of Si/C composite made by ball milling is limited, especially on the cycle life side. The link between Si and C by means of physical mixing is not strong enough. Once the content of Si or cycle number is a little high, the continuous conductive network is hard to maintain the integrity.

Compared with ball milling, TVD/CVD method can provide more solid carbon coating around Si via pyrolysis of polymers or organics. There are two factors influencing composite cycling performance: carbon source (precursor) and deposition parameters.

Carbon sources mainly include benzene series and alkyl compounds. For example, Yoshio M. et al.\textsuperscript{[42]} utilized the decomposition of benzene vapor at 1000°C with N\textsubscript{2} protection to deposit a carbon layer onto the surface of Si, obtaining the composite anode with a reversible capacity of 800 mAh/g. The carbon layer could suppress the decomposition of electrolyte on the surface of anode besides providing integral and continuous conductive networks. Some Si-containing polymers, like polysiloxanes\textsuperscript{[43]}, epoxy-silanes\textsuperscript{[44]}, and pitch-polysiane composites\textsuperscript{[45]}, are also good options of precursor because of better distribution of Si in the composite.

However, these materials are toxic or hypertoxic. What’s worse, some inactive chemical bonds, like Si-O-C, Si-O-Si or silicates, can be formed in the composite at high pyrolysis temperature (generally around 1000°C), leading to large irreversible capacity loss during the first cycle and the decrease of the specific capacity. Even using non-oxygen-containing Si precursors, like SiCl\textsubscript{4}\textsuperscript{[46]}, it is still hard to avoid the formation of inactive bonds. People have also attempted organic acid as carbon source with low toxicity and low pyrolysis temperature. For example, Guo L.P. et al.\textsuperscript{[47]} synthesized Si/C composites by pyrolyzing the mixture of Si nanoparticles and alginic acid dissolved in Na\textsubscript{2}CO\textsubscript{3} solution. With the increase of the temperature (from 400°C to 700°C), more amorphous C was produced and the composite exhibited better electrochemical performance. The reversible specific discharge capacity of Si/C at 700 °C was 560 mAh/g after 20 cycles.
Deposition parameters, including temperature and reaction time, mainly affect the thickness and morphology of C layer. For example, Liu H.K. et al. [48] mixed Si nanoparticles (<100 nm) in a citric acid/ethanol solution, then used spray-pyrolysis in air at low temperature (300–500 °C) to prepare a homogeneous C layer on the surface of spheroidal Si nanoparticles. The results showed low temperature (300 °C) results in large agglomerates of individual particles because of partially undecomposed citric acid, while high temperature (500 °C) makes C layer too thin (1 nm). The best sample with C layer of 40 nm thick was obtained at 400 °C, retaining a specific capacity of 1120 mAh/g after 100 cycles. Yu J.L. et al. [49] studied the effect of time on cycling performance. They used toluene as the precursor to make a uniform C layer on Si nanoparticles by dynamic CVD. The carbon thickness could easily be adjusted by changing reaction time. As shown in Fig. 2.8, the composite actually has complex 3D skeleton with the subtle microstructure. After 2h deposition, the sample with a C layer of 12 nm thick exhibited great cycle reversibility: a specific capacity of 1600 mAh/g at 0.3 A/g after 70 cycles. As far as I know, this is the best result for those simple mixing composites prepared by CVD/TVD till now.

![Fig. 2.8](image.png) [49]: a) SEM and b) TEM images of Si/C composites after 2h pyrolysis.

The drawback of TVD/CVD is about Si dispersion, especially using small molecular precursors like organic acid or short-chain polymer, resulting in Si aggregation to some degree and non-uniform carbon coating after pyrolysis. To overcome the inherent defect of TVD/CVD, people have tried to combine it with ball milling. For example, Liu H.K. et al. [50] mixed Si nanoparticles (80 nm) with PVA with weight ratio 1:9 by ball milling for 10h, and then used TVD at 600 °C under Ar flow to obtain Si particles with a disordered carbon layer, which exhibits high initial coulombic efficiency of 80.3%.
**Hierarchical structure type** As research continues, people found it was hard to further improve composite performance, especially cycle life, only with the aid of traditional mix or carbon coating, so they have paid more attention to the microstructure design, which in turn has greatly promoted the development of preparation methods. Most structures, aiming to optimize Si distribution, increase the strength of carbon layer, and reserve adequate space for Si volume change, belong to multidimensional hierarchical structures consisting of specific units. They can be divided into three groups.

The first one is hard template-assisted hierarchical structure. Two kinds of templates are commonly used: C-containing materials and SiO\(_x\). C-containing templates \(^{[51]}\) can be removed via calcination treatment and induce the formation of specific shape due to space effect. For example, Chen Y.J. et al. \(^{[52]}\) used a novel emulsion template to obtain Si/Carbon black (CB) composite with a specific capacity of 1300 mAh/g after 50 cycles. They modified CB with carboxyl group to improve the hydrophilic property and fabricated the stable oil-water interfaces via adjusting pH value. Si particles were surrounded by the interconnected CB network. After pyrolyzing, CB particles locating at the surfaces of emulsion droplets formed mesoporous cages that loosely encapsulate Si particles. Du Y.J. et al. \(^{[53]}\) prepared polystyrene (PS)@SiO\(_2\) precursor through tetramethyl orthosilicate (TEOS) hydrolyzing, and removed PS template at 600°C for 6h. After magnesiothermic reduction and toluene pyrolysis, interconnected sandwich structure carbon/Si-SiO\(_2\)/carbon nanospheres composite was formed (Fig.1.9a), which exhibits a high capacity of 1095mAh/g after 200 cycles. SiO\(_x\) templates can be removed by HF etching. Wang D.H. et al. \(^{[54]}\) firstly heated bulk SiO to form a composite composed of interconnected Si nanoparticles embedded in a SiO\(_2\) matrix. After removing SiO\(_2\) and filling C by thermal decomposition of acetylene gas at 620°C, microsized Si-C composites with a capacity of 1459 mAh/g after 200 cycles at 1A/g (Fig2.9 b) was obtained. Cui Y. et al. \(^{[55]}\) designed a non-filling C-coated porous Si microparticle by controllable chemical etching. Si/SiO\(_2\) composites were firstly wrapped by C from the pyrolysis of resorcinol-formaldehyde resin and then etched by HF, leaving the interior pore structures unfilled for Si expansion. The anodes can be deeply cycled up to 1000 times with capacity remaining around 1500mAh/g at 1A/g.
The second group is surface modification-assisted hierarchical structure. Through surface modification, some functional groups can be introduced on the surface of Si or C, forming covalent bonds or electrostatic attraction among particles. The covalent/electrostatic linkage is beneficial to retaining the composite capacity and cycle life. For example, Brousse T. et al.\textsuperscript{[56]} functionalized graphite flakes with aminophenyl groups in aqueous acidic media and bridged Si nanoparticles via a phenyl group. Compared with a simple mixture, this composite shows higher capacity retention (from 38\% to 52\%) after 50 cycles. Yu G.H. et al.\textsuperscript{[57]} fabricated a 3D ternary Si/conducting polymer/CNFs hybrid material which exhibits an excellent electrochemical performance (1600mAh/g over 1000 cycles at 3.3A/g). The affinity between Si and in-situ polymer coating could be attributed to the synergism of electrostatic effect between the negatively charged-OH group and positively charged polypyrrole polymer backbone and hydrogen bonding between phosphoric acid groups in the phytic acid and native SiO\textsubscript{2} at the Si surface. Since part of SiNPs may detach from the electronically conductive framework after some cycles, the 3D wrapping effect of SWCNTs can better confine SiNPs in the polymer framework to maintain the electrical connection within the entire electrode framework.
Figure 2.10: Scheme of fabricating Si-GO hybrid.

Graphene, a 2-D sheet with a sp² bond structure, should be emphasized because of its high electrical conductivity and thermal conductivity. More importantly, it also can be considered as a self-template due to its excellent physical behavior such as high mechanical strength, high elasticity and flexibility. Besides, graphene can be easily modified with some specific functional groups because of its large surface area with high reactive activity. Therefore, many Si/Graphene (or graphene oxide) composites have been studied. For example, Luo J.Y. et al. prepared crumpled graphene-encapsulated Si nanoparticles with a capacity of 940mAh/g after 250 cycles. A droplet generator produced a stream in which Si and graphene oxide particles were uniformly dispersed. After rapid evaporation, the crumpled graphene oxide sheets were formed due to isotropic capillary compression and Si particles were wrapped inside. Sun K.N. et al. studied the effect of surface charge on composite performance. They modified Si nanoparticles and graphene oxide (GO) with –NH₂ and –COOH group, respectively. After mixing, Si was firmly anchored on GO by covalent immobilization, as shown in Figure 2.10. Si/Graphene was formed via reductive anneal treatment. The homogeneous distribution of Si nanoparticles and the super high surface area of graphene supplied the hybrid enough internal space to accommodate the volume expansion during Li⁺ insertion process, resulting in long cycle lift at the high current rate. There still have some problems for 3D graphene-wrapped composites. Firstly, the improvement of cycle performance can be only achieved when graphene is dispersed well without any agglomeration caused by van der Waals force, but actually, good dispersability of graphene can be damaged easily during cycles. Secondly, its large surface area results in a thick SEI layer, indicating low initial Coulombic efficiency. Thirdly, graphene is much expensive than other carbonaceous materials, especially for single graphene sheets. Therefore, the application of graphene in LIB is still in the experimental stage and further research is urgently needed.
The third group is core-shell structures, generally consisting of active core (mainly Si) coated with a stable protective shell (mainly C). This structure can not only construct the conductive network and improve the structural and thermal stability, but also can reduce the decomposition of active materials via reducing the contact area between electrode and electrolyte. Wang D.H. et al. \[60\] studied the influence of buffer voids inside the shell on cycle performance of the composite. The SiO\(_2\) layer between Si (the core) and C (the shell) is used as a sacrificial template for generating void space. The void volume can be controlled by changing the thickness of SiO\(_2\). The results showed when the ratio of void to Si is around 3, the best performance of Si/C core-shell composite is achieved, which is consistent with huge volume expansion of 300% during lithiation process. Neither less nor more void leads to severe capacity fading after several cycles. Recently, Li M. et al. \[61\] fabricated a novel graphite/Si-porous carbon core-shell structure by spray drying/pyrolysis of slurry consisting of nano Si, graphite, and citric acid. Natural graphite is the core, and Si, which filled in the porous carbon matrix, is the shell. The capacity of this composite is about 600mAh/g after 100 cycles. Li S. et al. \[62\] used the similar method but different carbon sources to obtain a hierarchical core-shell structure, as shown in Fig.2.11. The inner C framework and surface C coating was from the pyrolysis of polyvinyl alcohol (PVA) and
polyacrylonitrile (PAN), respectively. Besides, the pyrolysis of PVA also provided butter space for Si volume change. Compared with Li M.’s result, the composite exhibits higher capacity but worse cycling life, indicating too complex structure may not bring better performance because the structure is hardly maintained. In addition, Cui Y. et al. [63] proposed a concept of “Yolk-Shell” (Fig.2.12), which shows excellent capacity (2800 mAh/g at C/10) and cycle life (1000 cycles with 74% capacity retention) even with conventional PVDF binder.

![Fig.2.12](image)

Fig.2.12 [63]: Schematics of lithiation process of Yolk-Shell C/Si structure.

Core-shell structure still has some problems. One is about uniformity, especially for large scale production. It’s hard to confirm all the active cores are coated with protective shell. Another problem is the complexity of preparation method, resulting in high cost and environmental issue.

2) Si/C co-axial structure

Si/C composite with coaxial tube/array is one of the most popular structures for LIB anode. C axis can provide firm connection with Si, fluent Li$^+$ transport pathway, and inhibit Si volume effect during cycles. There have three groups based on the location of Si.

The first group is Si/C composite with C core and Si shell. As the most commonly used template, CNTs have excellent conductivity, large surface area, good mechanical flexibility and high chemical stability. Therefore, the combination of Si with CNFs can produce the anode with improved electrochemical performance. For example, Wang W. et al. [64] used a simple two-step CVD method to deposit silicon nanoparticles on an aligned CNTs array substrate to obtain the composite with the capacity of 2000 mAh/g after 25 cycles. To improve the link between Si and CNTs, Martin C. et al. [65] used diazonium chemistry to bind Si and CNTs closely with enhanced

20
electron transport, which benefits the maintenance of Si axis during cycles. This composite exhibits high capacity of 1000 mAh/g after 35 cycles, two times than the simple mixture of Si and CNFs. Zhang Q. et al. [66] improved the core-shell structure further. They thought the traditional CVD only produced randomly aligned nanowire arrays without the effective control on size and array spacing. Highly non-uniform space distribution inevitably leads to insufficient space for strain relaxation at some certain locations. Therefore, they prepared a Si/CNTs core-shell nanowire array with controlled morphology. The vertically aligned CNTs core had large inter-wire spacing, and a cone shaped Si shell located along CNTs, as shown in Fig.2.13. This composite exhibits excellent capacity retention of more than 90% over 100 cycles at the current rate of 800 mA/g.

Fig.2.13 [66]: Schematic of fabrication processes and structure of the CNT-Silicon anode

The second group is Si/C composite with Si core and C shell. The corresponding capacity retention can often be improved by decreasing the diameter of Si axis or introducing enough space for volume effect. For example, Biswal S.L. et al. [67] firstly produced freestanding porous Si nanoarrays by means of electrochemical stripping from bulk Si and then coated C layer by pyrolyzing polyacrylonitrile (PAN). Chundong Wang et al. [68] deposited carbon nanoparticles on both internal and external surfaces of Si nanotubes (SiNTs) to obtain a core-shell structure, which delivers a high specific capacity of 2085 mAh/g at the current rate of 800 mA/g after 200 cycles. Recently, C-coated Si nanowires have been used as self-standing paper-like anode without any binder or conductive additives [69]. Besides, some conductive polymer coatings such as PEDOT [70] have also been studied to improve cycling performance of SiNWs core.
The third group is forming core-shell structure at the same time, commonly by using electrospinning technique. Electrospinning method has many advantages, such as simplicity, controlled diameter of the tube, and large-scale production. Generally, Si is the core. For example, Yoo J.K. et al. \cite{71} prepared highly porous continuous Si nanowires consisting of interconnected Si nanocrystals with a multi-level carbon coating, which shows a high reversible capacity of 1500mAh/g after 50 cycles. Electrospinning method also helps introduce other active additives except for C via adjusting the initial reactive solution. Jeong G. et al. \cite{71} added TiO$_2$ between Si core and C shell to act as a physical/chemical interfacial barrier, retarding exothermic reaction between highly lithiated Si phase and liquid electrolyte. Compared with other similar structures, SiNPs@Ti/C composite (Fig.2.14) exhibits very excellent rate capability of 939mAh/g after 50 cycles at 12A/g. The main problem of electrospinning method is relatively weak combination between Si and C in comparison with those made by CVD/TVD, leading to relatively short cycle life.

In brief, Si/C coaxial structure is good candidate for LIB anodes, mainly because of the significantly enhanced conductivity and structural durability. The major problem is the complicated fabrication process, which greatly increases the cost and thus prevents the commercial application.
3) Si/C film

Generally, few people have reviewed Si@C composite films because this classification is slightly inaccurate. Most active Si@C composites on the current collector can be considered as 2D active films with various unit structures. But there is indeed one case that is a different from the previous structures, which is often prepared by CVD or electrodeposition. For example, Kim S.O. et al. [72] deposited a diamond-like carbon with the thickness of 60 nm on the Si film. Wang J. et al. [73] synthesized the amorphous Si/C multilayer film by RF magnetic sputtering (RFMS) method. The first deposit layer consists of carbon to get good conductivity and strong adhesion with current collector, and the outermost layer is still carbon to avoid Si oxidation and film collapse. Some people have found that doping element such as boron [74] or aluminum [75] into C or Si film can also improve the composite cycling performance. Wu J.X. et al. [76] used a novel electrostatic spray deposition (ESB) to fabricate a Si embedded porous carbon/graphene hybrid film with layer-by-layer (LBL) structure, as shown in Fig2.15. Si nanoparticles cooperate with carbon framework and form sandwich-like morphology among graphene sheets, which demonstrates a high reversible capacity and good capacity retention without any binder.

![Diagram](image.png)

Fig2.15 [76]: a) Schematic of fabrication process for the LBL Si-C/G electrode; b) Schematic of the structure changes of the electrode during lithiation/delithiation process.
The problem of Si/C film is low active loading and packing density. If the film is too thick, the top part often exhibits different cycling stability from the bottom part, which leads to the internal stress to tear the film. Therefore, building better top-down electron/Li\(^+\) transport path is the hotspot for Si/C film preparation.

**Si/metal (Si/M) composites**

Metals have good conductivities and mechanical strength, which cannot only increase the anode conductivity, but also effectively inhibit Si volume effect during (de)lithiation process. In the Si/M composite, Si is generally dispersed into the metal substrate. The metals can be divided into two groups. One is Li-inert metal such as Fe, Cu, and Ni. For example, Zhang H.G. et al.\(^{[78]}\) prepared a 3D anode consisting of a Si film and a porous nickel metal scaffold, as shown in Fig.2.16. This metal framework cannot only improve the anode electrical conductivity, but also accommodate the volume change of Si during cycles, which exhibits high capacity of 2660 mAh/g at 0.3C after 100 cycles. Although it’s good for Si anode to improve the cycle life with the help of Li-inert metal, the energy density of composite must be decreased because the metals don’t involve in lithiation reaction. Therefore, more people have chosen Li-active metals as the substrate to avoid unnecessary loss of capacity, such as Mg and Sn. For example, Choi N.S. et al\(^{[79]}\) fabricated 1D Si/Sn nanowires with the capacity of 1050 mAh/g after 45 cycles at 300 mA/g. However, Li-active metals also have volume effect during lithiation, bringing bad effect on long cycles.

![Fig.2.16](image)

**Fig.2.16**\(^{[78]}\): Schematic of microstructure of Si-Ni electrode.

Actually, no matter what kind of metal is used, the whole competitiveness of Si/M composite on specific volumetric capacity is weaker than Si/C composite as mentioned before. Therefore, focusing on the improvement of cycle life may be the future direction of Si/M composite.
**Other composites**

Si can combine with the material with good Li\(^+\) conductivity, such as metal oxides \[^{80}\] ceramic materials \[^{81}\] or SiO\(_x\) \[^{82-84}\] to form a composite anode.

Take SiO\(_x\) as an example, it has smaller volume effect than that of Si during cycles because of less Si unit content. More importantly, a proper oxide layer can also suppress the volume expansion in some degree. Therefore, SiO\(_x\) has attracted much attention as a candidate for Si substitute. For example, Yoo H. et al \[^{83}\] prepared Si/SiO\(_x\) core-shell nanocoils anode by high-temperature annealing method with the help of Pt catalyst (Fig.2.17). Besides the buffer layer of SiO\(_x\) during cycles, the empty space inside the structure improves the contact of Si with electrolyte, leading to better transport of Li\(^+\). Therefore, this composite anode exhibits a great improvement of electrochemical performance with a specific capacity of 1600 mAh/g at 0.2 C after 70 cycles.

Fig.2.17 \[^{83}\]: Schematic of fabrication process for Si/SiO\(_x\) core-shell nanocoils anode electrode.

However, as the increase of oxygen content, cycle performance of the composite becomes worse because of the decrease of mechanical strength of oxide layer and excessive inactive Li-containing compounds formed by Li insertion.

**2.4 Electrophoretic deposition**

Electrophoretic deposition (EPD) is commonly employed in processing of a variety of coatings \[^{85,86}\] and free-standing objects \[^{85}\]. EPD is achieved via the motion of charged particles, dispersed in a suitable suspension, towards an electrode under an applied electric field. Electrophoretic motion of charged particles during EPD results in the accumulation of particles and the formation of a homogeneous deposit at the relevant electrode. The deposition of positively charged particles on negative electrode is called cathodic electrophoretic deposition (c-EPD); while the deposition of negatively on positive electrode is called anodic electrophoretic deposition (a-EPD), as shown in Fig2.18.
Generally, EPD can be applied to any solid with the small particle size (<30 um) and colloidal suspensions [85, 86], mainly including two steps. Firstly, particles suspended in a liquid are forced to move towards an electrode by applying an electric field (electrophoresis). Then, the particles gather at the electrode and form a coherent deposit layer (deposition). Compared with other deposition methods, EPD has many advantages, such as low cost, process simplicity, uniformity of deposits, controllable deposit morphology, and no limit of shape of substrate. Some people even have used EPD to obtain dense films on porous non-conductive substrates [87]. Besides, EPD only needs suspensions with relatively low solids loading and low viscosity, which implies convenient after-treatment procedures.

![Fig.2.18](image)

**Fig.2.18 [91]:** Schematic illustration of electrophoretic deposition process. a) cathodic EPD; b) anodic EPD.

### 2.4.1 EPD mechanism

As mentioned in the previous part, EPD is a process where charged particles travel through a suspension under an external electric field. Charged particle is the precondition, therefore, the DLVO theory has been considered as the fundamental mechanism of EPD [88-90]. Based on this theory, some other theories [91] have been also proposed to explain the particle behavior during EPD, mainly including flocculation by particle accumulation, particle charge neutralization, electrochemical particle coagulation, and electrical double layer distortion and thinning mechanism.

1) DLVO theory

DLVO (Derjaguin-Landau-Verwey-Overbeek) theory describes the force between charged particles consisting of the van der Waals attraction potential and repulsive electrostatic potential, given by Equation 2.11:
\[ V_T = V_A + V_R \]  \hspace{1cm} 2.11

where \( V_T \) = total energy, \( V_A \) = attractive energy, \( V_R \) = repulsive energy.

And the potential energy curve for DLVO theory is shown in Fig.2.19.

When the distance between particles tends to be infinite, \( V_T \) is 0. As the decrease of the distance, \( V_A \) becomes the dominant force and the absolute of \( V_T \) is increased gradually to the maximum value. In this stage, although particles attract each other, the distance is too long to cause serious particle aggregation. If the distance continues to decrease, \( V_R \) begins to dominate over \( V_A \) leading to the change of the force between particles from attraction to repulsion. And the maximum repulsive force can be obtained when the distance is decreased to a specific value. At this moment, the particles in the suspension show the highest stability. If the particle distance is decreased further, \( V_A \) becomes dominant again, so does the absolute of \( V_T \), causing quick flocculation of particles.

Based on the DLVO theory, the stability of suspension depends on the total energy of interaction between particles, which can be greatly influenced by surface charge and particle concentration.

Fig.2.19: Total potential energy versus interparticle distance curve between two particles.

2) Flocculation by particle accumulation

This mechanism was firstly proposed by Hamaker and Verwey\textsuperscript{[92]}, mainly appropriate for explaining the deposition of coatings on porous membranes\textsuperscript{[93]}. They found the external
applied electric field makes particles moving towards the electrode to accumulate during EPD. When the particles are close enough to each other, the pressure caused by arriving particles can overcome the repulsive force between particles, and the deposition happens by means of the gravitation.

3) Particle charge neutralization mechanism

This mechanism was proposed by Grillon et al.\cite{94}, explaining the deposition of single particles and monolayers in very dilute suspensions. They though all the charged particles become neutral as contacting with the electrode. However, this mechanism is not suitable for long-time EPD, or the deposition on the substrate locating between electrodes.

4) Electrochemical particle coagulation mechanism

This mechanism was proposed by Koelmans et al\cite{95} to explain the deposition of particles with increased electrolyte concentration close to the electrode. Through calculating the ionic strength of particles next to the electrode under different electric fields, they found the similar value as that requires to coagulate in the suspension, indicating the decrease of the repulsive force between particles. They thought it should be caused by the increase of the electrolyte concentration close to electrode, leading to lower surface charge density. To be specific, this mechanism is suitable for the system that can generate $-\text{OH}^-$ during EPD\cite{91}.

5) Electrical double layer (EDL) distortion and thinning mechanism

This mechanism was proposed by Sarkar and Nicholson\cite{96} to explain the deposition of particles with a constant high electrolyte concentration near the electrode. They thought when a positive charged particle is moving towards to the cathode, the particle double layer is distorted with thinner ahead and wider behind due to the external electric field and fluid dynamics. Then, the negative ions in the tail of a particle prefer to attract cations locating the head of another one with a distorted double layer moving towards the cathode. Finally, the coagulation is achieved.

2.4.2 Factors affecting EPD

The factors affecting EPD can be divided into two groups: 1) suspension properties and 2) processing parameters.

**Suspension properties**

1) Particle size

A stable suspension is necessary for a successful EPD process, or else a nonuniform deposit layer will be obtained, such as consisting of a thinner top and a thicker bottom if the
substrate is vertically placed. A suspension with large particles (>20 μm) is usually unstable because the settlement easily occurs under gravity effect. Therefore, particles with the sizes of 1 ~ 20 μm has been suggested[91]. Recently, with the rapid development of nanotechnology, many coatings with nanoparticles have been prepared by EPD[97,98]. Well and stable dispersion of nanoparticles in the suspension is a precondition. For example, Zhu G.Z. et al[98] prepared uniform Bi$_2$O$_3$ nano-films in the ethanol suspension with controlled thickness from 6 μm to 18 μm. Paper-manufacturing waste sodium lignin sulfonate (MZS) is used as the dispersant to avoid the aggregation of nanoparticles, as shown in Fig.2.20.

Particle size also plays an important role in improving the density of the deposited layer. For example, Das D. et al[99] found narrow size distribution in the suspension is beneficial to obtain the uniform deposit with high packing density.

![Fig.2.20](image)

Fig.2.20[98]: Schematic of the stabilization of Bi$_2$O$_3$ nanoparticles in the ethanol and EPD process.

2) Dielectric constant

High dielectric constant leads to high ionic concentration in the suspension, which will reduce the thickness of double electric layer of particles and finally slow down the electrophoretic mobility. Low dielectric constant leads to failing deposition due to the decreased dissociative power. Therefore, the suitable range is about 12 ~ 25[91]. The dielectric constants of some common liquids are shown as Table2.2.

<table>
<thead>
<tr>
<th>Liquid</th>
<th>Dielectric constant</th>
</tr>
</thead>
<tbody>
<tr>
<td>Ethanol</td>
<td>22.4</td>
</tr>
<tr>
<td>Acetone</td>
<td>20.7</td>
</tr>
</tbody>
</table>

Table2.2: Dielectric constants of liquids
<p>| | |</p>
<table>
<thead>
<tr>
<th></th>
<th></th>
</tr>
</thead>
<tbody>
<tr>
<td>n-Propanol</td>
<td>20.33</td>
</tr>
<tr>
<td>Iso-propanol</td>
<td>19.92</td>
</tr>
<tr>
<td>n-Butanol</td>
<td>17.51</td>
</tr>
</tbody>
</table>

3) Conductivity of suspension

Like dielectric constant value, suspension conductivity also cannot be too low or too high. If it’s too low, the particles will charge themselves under the external electric field and lose the stability. If it’s too high, the double electric layer will be reduced seriously and the electrophoretic mobility will be decreased. The specific range of suspension conductivity for EPD depends on the temperature, dispersant concentration and the applied voltage \(^{[101]}\).

4) Zeta potential

A stable suspension must have a high zeta potential (\(\zeta\)-potential) besides keeping the relatively low ionic conductivity. \(\zeta\)-potential \(^{[102]}\) is the electric potential in the interfacial electric double layer (EDL) at the location of the slipping plane relative to a point in the bulk fluid away from the interface, as shown in Fig.2.21, which indicates the stability of colloidal dispersions and determine the migration direction of particles.

![Diagram](image)

**Fig.2.21** \(^{[102]}\): Diagram shows the ionic concentration and potential difference as a function of distance from the charged surface of a particle suspended in a dispersion medium.
The magnitude of the zeta potential shows the degree of electrostatic repulsion between adjacent, similarly charged particles in the suspension. When ζ-potential is small, attractive forces may exceed the repulsion and particles agglomeration occurs. On the contrary, particles with high ζ-potential (negative or positive) will repulse each other against coagulation or flocculation, which will lead to high particle packing density during deposition. Most people think the absolute value should be over 30mV to keep the suspension stable [91], and it can be easily influenced by particle size, solvent, pH value, additives such as surfactant or conductive agent [103, 104].

**Processing parameters**

1) Deposition time

In most cases, the influence of deposition time on EPD can be divided into two stages. During the early time with a given constant voltage, the deposition yield has a linear relationship with the deposition time. The corresponding equation (Hamaker’s Equation) is shown in Eq.2.12 [105].

\[
\frac{dY}{dt} \propto f \mu ECS \tag{2.12}
\]

where \( Y = \) yield, \( t = \) deposition time, \( f = \) deposition factor, \( \mu = \) electrophoretic mobility, \( E = \) electric field strength, \( C = \) concentration, \( S = \) surface area.

As the increase of the deposition time, the deposition will gradually arrive at a saturation point with less increase. Fig.2.22 [106] shows a typical example of Al/NiO coating in the mixture of ethanol-acetylacetone (1:1 in volume) with the increasing deposition time. The linear relation between deposition mass with deposition time in short time and parabolic relation in prolonged time can be observed. Besides, the electric field in the suspension will decrease as the formation of a deposit layer on the electrode.
Fig. 2.22\textsuperscript{[106]}: Variation of deposition weight with time during EPD of Al/NiO in the mixture of ethanol-acetylacetone (1:1 in volume).

2) Applied voltage

Generally, for a given suspension system, both deposition rate and weight is proportional to the applied voltage\textsuperscript{[107]}. And different suspension systems require different ranges of applied voltage.

Fig. 2.23\textsuperscript{[108]}: a) Experimental set-up for the aqueous EPD process; b) deposition rate as function of the electric field strength for different materials (time: 3min).

In the aqueous suspension, the problem of water hydrolysis cannot be ignored. If the applied voltage is higher than hydrolysis voltage, oxygen and hydrogen gas will be generated around the electrode surface, leading to the formation of porous and inhomogeneous deposition layer. To solve this problem, some particular substrates or semi-permeable membranes have been
introduced. For example, Tabellion J. et al.\textsuperscript{[108]} deposited different particles (silica, SiC, and zirconia) onto the 3D porous polymer moulds in the water (Fig.2.23a), and each particle shows the linear relationship between the deposition rate with the voltage (Fig.2.23b).

In the non-aqueous suspension, hydrolysis effect disappears and higher voltage can be used during EPD. For example\textsuperscript{[109]}, in the isopropyl alcohol suspension, a dense carbon nanotubes film can be prepared onto the glass plates with ITO coating by EPD with the voltage range of 100 – 200V. However, too high voltage can bring bad effects on the quality of the deposit layer\textsuperscript{[91]}. Firstly, too high voltage can cause the turbulence in the suspension to disturb the regular coating on the substrate; secondly, particles will move too fast towards the electrode to form a dense structure.
Current research focuses on anode materials, particularly those based on graphite, as they excel in LIB applications due to their stable charging/discharging platforms, good cycle life, and low costs. However, their capacity/energy density fail to meet the demands for next-generation LIBs utilized in electric vehicles and portable devices. New anode materials with higher specific capacity are urgently needed.

Silicon (Si) is recognized as a promising anode material because of its highest theoretical specific capacity and abundant natural reserves. Nevertheless, its application is constrained by issues like huge volume change and poor conductivity. To address these challenges, numerous methods have been developed, yielding Si-containing anode materials with enhanced electrochemical properties, as mentioned in Chapter 2.3. However, from a practical perspective, few Si-containing anode materials, which exhibit very high capacity (>600 mAh/g) and long cycle life (>100 cycles), can be promoted in industry. The (micro)-structure design is a priority in laboratory work, not the cost of production or environmental concerns. Commercial composite anode materials consisting of Si and graphite are typically prepared by ball milling, but these are limited by Si content (no more than 10 wt%) and challenging to improve further.

Based on the above, the choice of the preparation method is the first consideration in this thesis. Given its high efficiency, simple operation, and low cost, EPD is the only method to be used. Therefore, the objective of this thesis is preparing Si/C composite anode materials with uniform morphology and improved electrochemical properties by multicomponent EPD.

This thesis primarily consists of two parts as follows:

1) The first part demonstrates the feasibility of multicomponent EPD for Si/CNFs systems. Based on zeta potential and settling rate analysis, the optimal pH range and concentration for the (meta)stable Si/CNFs suspensions are determined. Then, the
composite films on the Cu foil with different ratio of Si to CNFs are prepared by EPD. The influences of applied voltage and deposition time on the film growth and the corresponding electrochemical properties are studied.

2) The second part describes the preparation of three kinds of Si/CNFs composite films with improved electrochemical properties by EPD. Some functional groups (Si-OH, Si-NH$_2$) or carbon layer (Si-C) are introduced onto Si surface. Then, the suspension properties and EPD process for Si-OH/CNFs, Si-NH$_2$/CNFs and Si-C/CNFs systems are investigated, respectively. The growth mechanisms and the reason for the improvement of electrochemical properties are discussed.
Chapter 4

EXPERIMENTAL METHODS

4.1 Materials and Equipment

Table 4.1: Experimental materials and chemical reagents.

<table>
<thead>
<tr>
<th>Chemical reagents</th>
<th>Reagent specifications</th>
<th>Corporation</th>
</tr>
</thead>
<tbody>
<tr>
<td>Silicon nanoparticles (SiNPs)</td>
<td>100 nm</td>
<td>Sigma - Aldrich</td>
</tr>
<tr>
<td>Carbon nanofibers (CNFs)</td>
<td>Graphitized, D x L</td>
<td>Sigma - Aldrich</td>
</tr>
<tr>
<td></td>
<td>100 nm x 20 – 200 μm</td>
<td></td>
</tr>
<tr>
<td>Carbon black (CB)</td>
<td>Cell grade</td>
<td>MTI Corp.</td>
</tr>
<tr>
<td>Hydrochloric acid (HCl)</td>
<td>ACS reagent, 37%</td>
<td>Sigma - Aldrich</td>
</tr>
<tr>
<td>Lithium hydroxide (LiOH)</td>
<td>Anhydrous, 98%</td>
<td>Alfa Aesar</td>
</tr>
<tr>
<td>Nitric acid (HNO₃)</td>
<td>ACS reagent, 70%</td>
<td>Sigma - Aldrich</td>
</tr>
<tr>
<td>Sulfuric acid (H₂SO₄)</td>
<td>ACS reagent, 95.0 – 98.0%</td>
<td>Sigma - Aldrich</td>
</tr>
<tr>
<td>Hydrogen peroxide (H₂O₂)</td>
<td>ACS reagent, 30 wt.% in H₂O</td>
<td>Sigma - Aldrich</td>
</tr>
<tr>
<td>Hydrofluoric acid (HF)</td>
<td>48 wt.% in H₂O</td>
<td>Sigma - Aldrich</td>
</tr>
<tr>
<td>Lithium (Li)</td>
<td>Cell grade</td>
<td>MTI Corp.</td>
</tr>
<tr>
<td>Polyvinylidene Fluoride (PVDF)</td>
<td>Cell grade</td>
<td>MTI Corp.</td>
</tr>
<tr>
<td>N-Methyl-2-pyrrolidinone (NMP)</td>
<td>ACS reagent</td>
<td>Sigma - Aldrich</td>
</tr>
<tr>
<td>Sodium Dodecyl Sulfonate (SDS)</td>
<td>ACS reagent, ≥99.0%</td>
<td>Sigma - Aldrich</td>
</tr>
<tr>
<td>Triton X-100 (TX-100)</td>
<td>For electrophoresis</td>
<td>Sigma - Aldrich</td>
</tr>
<tr>
<td>Quaternary ammonium compound (QAC)</td>
<td>ACS reagent</td>
<td>Sigma - Aldrich</td>
</tr>
<tr>
<td>LIB commercial electrolyte (LiPF$_6$/EC + DMC)</td>
<td>Cell grade</td>
<td>MTI Corp.</td>
</tr>
<tr>
<td>LIB separator (Celgard 2400)</td>
<td>Cell grade</td>
<td>MTI Corp.</td>
</tr>
<tr>
<td>Ethanol</td>
<td>ACS reagent, Anhydrous</td>
<td>Carolina Corp.</td>
</tr>
<tr>
<td>Sucrose ($C_{12}H_{22}O_{11}$)</td>
<td>ACS reagent, $\geq 99.5%$ (GC)</td>
<td>Sigma - Aldrich</td>
</tr>
<tr>
<td>Lithium borate (Li$_2$B$_4$O$_7$)</td>
<td>99.997%</td>
<td>Alfa Aesar</td>
</tr>
</tbody>
</table>

Table 2.2: Lab equipment

<table>
<thead>
<tr>
<th>Equipment</th>
<th>Model</th>
<th>Corporation</th>
</tr>
</thead>
<tbody>
<tr>
<td>Ultrasonic bath</td>
<td>3L Stainless Steel Cleaner, Hot power: 100W, Ultrasonic power: 120W, Frequency: 40kHz</td>
<td>Spectralab Corp.</td>
</tr>
<tr>
<td>Magnetic stirrer</td>
<td>PC-400D</td>
<td>Corning Corp.</td>
</tr>
<tr>
<td>Ultra-precision balance</td>
<td>AXIS ALZ Analytical balance $200g \times 0.01mg$</td>
<td>CSG Corp.</td>
</tr>
<tr>
<td>Arbin instrument</td>
<td>BT2143 32 channel</td>
<td>Arbin Corp.</td>
</tr>
<tr>
<td>Electrochemical workstation</td>
<td>Autolab PGSTAT128N</td>
<td>Metrohm Corp.</td>
</tr>
<tr>
<td>Glove box</td>
<td>$H_2O &lt; 0.5$ ppm $O_2 &lt; 1$ ppm</td>
<td>Self-made</td>
</tr>
<tr>
<td>Vacuum drying oven</td>
<td>Across International 1.9 Cu Ft</td>
<td>TERPP Corp.</td>
</tr>
<tr>
<td>Tubular furnace</td>
<td>OTF-1200x-4-C4LVS</td>
<td>MTI Corp.</td>
</tr>
<tr>
<td>DC power supply</td>
<td>Genesys$^{TM} 600 – 1.3$</td>
<td>TDK-Lambda Corp.</td>
</tr>
</tbody>
</table>
4.2 Experimental method

1) Anode materials and suspension preparation

See the following chapters for details.

Zeta potential is tested by Zetasizer Nano (Malvern Corp.).

2) EPD procedure

Cu foil (1 × 1, 2 × 2, 4 × 4 cm$^2$) and the stainless steel were used as the working electrode and the counter electrode, respectively. EPD was performed under potentiostatic conditions at applied voltage of up to 75 V/cm and deposition times of up to 15 min, as shown in Fig.4.1.

![Diagram of EPD procedure](image)

Fig.4.1: Diagram of EPD procedure

After the deposition, the Cu foil with the deposited layer was successively immersed into the diluted HCl and water several times to remove the impurities, and dried in Argon for 2h at 150°C.

3) Fabrication of coin cell batteries

Half cells were made using a small piece of as-prepared CNFs/Si film (0.8 × 0.8 cm$^2$) as the working electrode, lithium metal foil as the counter electrode, and Celgard 2400 as the separator. The liquid electrolyte was 1M LiPF$_6$ in ethylene carbonate / diethyl carbonate / dimethyl carbonate (1:1:1 volume ratio, 1% VC). The cells (CR2032) were fabricated in an argon-filled glovebox (moisture and oxygen levels less than 1ppm), as shown in Fig.4.2.

4) Electrochemical measurement

Cell’s cycling performance was tested with the voltage range of 3 ~ 0.05V at different current rates of 400 mA/g – 1600 mA/g. The effective active materials consist of CNFs and Si.
During the test, Li+ inserting into Si/CNFs composite film is considered as the discharging process, and Li+ extraction is charging process.

The cyclic voltammogram (CV) were measured with the voltage range of 1.8 ~ 0.01 V at the scanning rate of 0.5 mV/s.

4.3 Material Characterization

The film morphology was tested by scanning electron microscope (SEM, JSM-7600F, acceleration voltage: 5 ~ 10V) and transmission electron microscopy (TEM, JSM-2010).

The film component was tested by energy dispersive X-ray elemental analysis (EDX, JSM-7600F EDS system) and X-ray photoelectron spectroscopy (XPS, PHI VersaProbe 5000, Energy range: 0 – 1486.6 eV Binding Energy with Al Kα source).

The content of Si in the composite film was tested by thermogravimetric analysis (TGA, SDT Q600 v20.9 analyzer) in the air. The sample was scrapped off Cu foil by a knife, placed in an alumina pan, and heated from 20°C to 900°C with a heating rate of 10°C/min.

After cycling performance, some cells were disassembled in the glovebox and the working electrodes were washed by N-methyl-pyrrolidone (NMP), diluted HCl and ethanol, and dried at 80°C in the vacuum oven before they were observed by SEM.
Chapter 5

MULTI-COMPONENT EPD OF Si/CNFs COMPOSITION ANODE FOR LIB

5.1 Introduction

Currently, graphite is the most widely used anode material in the commercial LIBs. However, the low theoretical specific capacity (372 mAh/g) cannot meet the demands on higher energy density for future portable electronic devices and electric vehicles. As a potential replacement, silicon has been attracting more attention due to its large theoretical specific capacity (up to 4200 mAh/g) and low costs. To make Si anode practical, two main problems need to be solved: huge volume change (~300%) during Li\(^+\) insertion/extraction and low conductivity. One popular method is to fabricate the composite anode consisting of Si and carbonaceous materials. Because of good toughness, high electronic conductivity and high Li\(^+\) conductivity, carbonaceous materials cannot only improve the anode conductivity, but also inhibit the volume change of Si and particle aggregation during cycles, which finally improves the electrochemical properties of Si-based anode.

Compared with the traditional preparation methods of Si/C anode (Chapter 2.3), EPD has been attracting increasing interest as a versatile, efficient and economical technique for the large-scale preparation of coatings or films of ceramics, oxides and carbonaceous materials on conductive substrates\(^9\). It can be applied to any particles with small sizes (<30 μm) in suspensions with relatively low solids loading. Generally, the deposition occurs on the surface of conductive substrate, but these days some researches have used porous non-conductive substrates to achieve a successful EPD process via infiltration/adsorption.

The factors that influence the quality of the film by EPD can be divided into two groups. One has focused on the physical properties of the particle and suspension, such as the total concentration, conductivity and pH value. These factors are usually interacting and influencing each other, which finally decide the size of the electric double layer of particles and the stability of the suspension. Zeta potential is chosen to reflect the combined influence of these factors.
Besides, the settling rate can be used as a supplement from a macro view. Another group has been concerned with the dynamic parameters of EPD procedure, such as the applied voltage and deposition time.

Till now, many people have used EPD technique to fabricate CNTs\textsuperscript{[110]}/CNFs-containing\textsuperscript{[111,112]} or SiO\textsubscript{2}-containing structures\textsuperscript{[113,114]}. However, few reports on EPD for Si-containing structures have been published.

Compared with the single-component EPD, the multi-component EPD is more complicated. On the one hand, each component has its own surface charge and mobility rate under a given condition; on the other hand, the interaction between different components may influence their original behavior during EPD process. Therefore, it’s very difficult to obtain a homogeneous composite film by multi-component EPD.

In this section, a uniform CNFs/Si composite film without binder was prepared by multi-component EPD, which exhibits improved electrochemical properties. The influences of pH value, solvent, concentration, applied voltage and deposition time on the deposit film were studied and the dynamics model was built.

5.2 Structural design and experiment

5.2.1 Structural design

Carbon nanofibers (CNFs) and commercial Si nanoparticles (SiNPs) were chose as the raw materials. For the composite anode, a continuous conductive framework and well distribution of SiNPs is necessary for the improvement of electrochemical properties. During the charging/discharging process, the physical contact between Si and CNF should be maintained to make ion/electron-transfer fluent; meanwhile, the interspace of CNFs net can alleviate the impact of the volume change of SiNPs.

Therefore, two objectives would be achieved in this section.

Firstly, the feasibility of multi-component EPD for CNFs/Si system would be verified. There are at least two requirements. 1) The CNFs/Si suspensions with a large range of the concentration can keep stable or metastable; 2) the operation should be as simple and efficient as possible, especially in comparison with other traditional ways like CVD or ball milling.

Secondly, a series of composite anodes would be prepared by EPD, which has a target structure like this (Fig. 5.1): a 3D-conductive net consisting of CNFs is formed directly on the Cu foil and SiNPs are randomly distributed in it. Such structure has some features: 1) the conductive
net is intact and has a strong adhesive force with Cu foil without any binder; 2) no serious SiNPs aggregation happens; 3) the weight ratio of Si to CNFs and total loading can be adjusted simply, and in a specific range, the composite films can exhibit good electrochemical properties (long cycle life and high capacity).

Fig.5.1: Structure diagram of CNFs/Si anode by multi-component EPD.

5.2.2 Experiment

The steps are listed as follow.

1) Carboxylation of CNFs. CNFs were refluxed in the mixture of concentrated nitric and sulfuric acids ($V_{H_2SO_4} : V_{HCl} = 1:2$) for 3h at 80°C. After acid purification, CNFs were washed to neutral by deionized water and dried in air for 3h at 100°C.

2) Preparation of suspensions. The mixture of CNFs/Si with different weight ratios were dispersed into 50 mL ethanol followed by ultrasonication for 2h. LiOH and HCl were used to adjust the corresponding pH value of 1~11.

3) Zeta potential measurement and EPD procedures. See Chapter4.

5.3 Single-component EPD

5.3.1 Carboxylation of CNFs

Carbon nanofibers (CNFs), consisting of curled-up graphite sheets, have been widely used in many fields such as hydrogen storage, secondary battery and medical equipment due to the light weight, high flexibility and intensity, excellent thermal conductivity and electrical
conductivity \[^{115, 116}\]. However, CNFs are often entangled or aggregated, and have some defects and impurities such as the catalytic metal particles. To overcome the disadvantages, an effective way – chemical modification/purification – has been developed. A typical path is using acid reflux to oxidize the surface defects, shorten the fiber length and remove the impurities \[^{117}\], as shown in Fig.5.2. Three commonly used acid solutions \[^{116}\] are HNO\(_3\), H\(_2\)SO\(_4\)/HNO\(_3\) and H\(_2\)SO\(_4\)/H\(_2\)O\(_2\). As a result, the carboxyl groups (-COOH) are introduced onto CNFs surface, leading to better dispersion in the polar solution. Because of high requirement on the suspension stability during EPD, surface modification of the pristine CNFs (p-CNFS) is necessary.

![Fig. 5.2](image1)

**Fig. 5.2** \[\text{117}\]: Surface modification of CNFs in the acid solution

Different treatment conditions result in different degrees of modification, which can be quantitatively analyzed by the amount of –COOH groups on the surface.

As shown in Fig.5.3a, p-CNFS have smooth surface with the length of tens of micrometers and diameter of ~200 nm. After acid treatment, the size is generally maintained but the surface becomes rough (Fig.5.3b). Some CNFs with opening-end can be also observed (inset Fig.5.3b), which is a typical characteristic of acid-treated CNFs.

![Fig. 5.3](image2)

**Fig. 5.3**: SEM images of a) p-CNFS and b) pretreated CNFs in the mixed acid.
Fig 5.4 shows thermogravimetric curves of different CNFs, which can be divided into three parts: dehydration area due to the release of surface moisture (0 – 100°C), reaction area due to the degradation of –COOH groups (100 – 750°C), and stable area (>750°C). The specific weight-loss ratios of each sample are listed in Table 5.1. It's noticed that c-CNFs only have a small number of –COOH groups (2.34%), and the content of carboxyl group will be increased to 6.79% after 2h acid treatment.

Table 5.1: Losing mass of CNFs with different acid treatment time.

<table>
<thead>
<tr>
<th>Sample</th>
<th>Losing weight in 100°C wt /%</th>
<th>Losing weight in 750°C wt /%</th>
<th>-COOH content (molar ratio) x /%</th>
</tr>
</thead>
<tbody>
<tr>
<td>c-CNFs</td>
<td>3.4</td>
<td>11.1</td>
<td>2.34</td>
</tr>
<tr>
<td>CNFs-COOH (0.5h)</td>
<td>5.1</td>
<td>17.7</td>
<td>3.92</td>
</tr>
<tr>
<td>CNFs-COOH (2h)</td>
<td>4.5</td>
<td>25.0</td>
<td>6.79</td>
</tr>
</tbody>
</table>

Fig 5.4: Thermogravimetric curves of a) p-CNFs, b) CNFs treated by mixed acid refluxing (0.5h), c) CNFs treated by mixed acid refluxing (2h).
Fig.5.5 shows FTIR spectra of different CNFs, and the specific band assignments are listed in Table5.2.

Table5.2: Assignment of infrared absorptions for pure and acid-treated CNFs.

<table>
<thead>
<tr>
<th>Assignment</th>
<th>Wavenumber (literature)[^{118, 119}] (cm(^{-1}))</th>
<th>Wavenumber (experiment) (cm(^{-1}))</th>
</tr>
</thead>
<tbody>
<tr>
<td>absorbed water</td>
<td>3450</td>
<td>3400</td>
</tr>
<tr>
<td>C=O stretching carbonyl &amp; carboxy</td>
<td>1725 – 1714</td>
<td>1720</td>
</tr>
<tr>
<td>O-H bending</td>
<td>1600 – 1630</td>
<td>1630</td>
</tr>
<tr>
<td>C-C vibrating</td>
<td>1520 - 1530</td>
<td>1530</td>
</tr>
<tr>
<td>C-C stretching</td>
<td>1217 – 1188</td>
<td>1200</td>
</tr>
<tr>
<td>C-O stretching</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Isolated aromatic C-H out-of-plane bending</td>
<td>882 – 872</td>
<td>810</td>
</tr>
</tbody>
</table>

Fig.5.5: FTIR spectra of CNFs with or without surface modification
For c-CNFs, the absorption at 3400 cm\(^{-1}\) are due to surface moisture and the peak at 1530 cm\(^{-1}\) can be assigned to the C-C skeleton vibration. Because of the existence of a little carboxyl groups, the absorptions at 1720 and 1200 cm\(^{-1}\) is observed, which are attributed to the C=O stretching vibration and C-O stretching vibration, respectively. After acid treatment, more carboxyl groups are introduced on the surface, the intensity of peak at 1630 cm\(^{-1}\) is enhanced, which is attributed to the O-H bending vibration.

5.3.2 EPD of CNFs

1) Zeta potential

In a given solution, a charged particle can attract or repel the free ions to achieve the redistribution of free ions around the particle surface, leading to the formation of the electric double layer (EDL).

Based on the Gouy-Chapman model \([120]\), the Debye length (\(\kappa^{-1}\)), representing a distance from the charged surface to a point where the potential decreases to 33% of the surface potential, has been used to estimate the thickness of the electric double layer although it’s actually smaller than the latter. \(\kappa^{-1}\) can be expressed by Eq.5.1.

\[
\kappa^{-1} = \left( \frac{k_B T}{2 e^2 z^2 n_\infty} \right)^{1/2}
\]

where:

\(\varepsilon\) = the dielectric permittivity of the solvent;
\(k_B\) = the Boltzmann constant;
\(T\) = Kelvin temperature;
\(e\) = the electron charge;
\(z\) = the valence of the ions;
\(n_\infty\) = the bulk concentration of the ions;

Therefore, \(\kappa^{-1}\) will be decreased as the increase of the concentration/valence of free ions if other physical parameters are fixed, and generally, \(\kappa^{-1}\) is lower than 10 nm when the electrolyte concentration is low (<0.1M).

The potential distribution in the spherical EDL can be described by the Stern model and the Debye-Huckel Approximation \([121]\], as shown in Fig.5.6. If the particle radius (a) is much larger than \(\kappa^{-1}\) (\(ka > 1\)), the potential distribution (\(\psi\)) in the radial direction can be given by Eq.5.2.
\[
\psi = \psi_d \exp(-\kappa x)
\]

where:

\(\psi_d\) = the Stern plane potential;

\(x\) = the distance to the particle surface;

Therefore, as the decrease of \(\kappa^{-1}\), \(\psi\) will be also decreased.

Fig. 5.6 [121]: a) diagram of the EDL according to the Stern model; b) diagram of the electric potential profile. The diffuse double layer starts from the Stern plane.

Combining with Eq. 5.1 and Eq. 5.2, \(\psi\), including zeta potential, is mainly influenced by the free ions’ concentration and valence in a given solution at room temperature. To obtain the relatively high zeta potential, the basic idea is to use low-valence ions as the electrolyte/pH modifier and keep the concentration of additives low. Therefore, in this chapter, HCl solution and LiOH is chose.

In ethanol, as shown in Fig 5.7, the pristine CNFs (p-CNfs) show low stability with the maximum zeta potential values of 21 mV at pH0.25 and -18 mV at pH 11. The related I.E.P. value is about 5.5. After surface modification, -COOH groups are introduced, leading to the smaller I.E.P. and better stability due to the improved electrostatic repulsive force on CNFs surface. Two modified samples display a similar trend of pH effect on zeta potential, and more – COOH groups lead to a more negative zeta potential value in the range of pH 7~11.

Fig. 5.8 shows the influence of solvents on zeta potential of CNFs-COOH (7%). Except for ethanol, three representative solvents was chose and the related physical parameters are listed.
Because CNFs concentration is very small (1 mg/mL), the influence of absolute viscosity can be ignored.

Table 5.3: Physical parameters of solvents

<table>
<thead>
<tr>
<th>Solvent</th>
<th>Dielectric constant</th>
<th>Absolute Viscosity (@25°C cP)</th>
<th>Electrical conductivity (S/cm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Distilled Water</td>
<td>79.7</td>
<td>0.89</td>
<td>10^{-6}</td>
</tr>
<tr>
<td>Acetone</td>
<td>20.7</td>
<td>0.33</td>
<td>5.0x10^{-9}</td>
</tr>
<tr>
<td>N,N – Dimethylformamide (DMF)</td>
<td>36.7</td>
<td>0.82</td>
<td>6.0x10^{-8}</td>
</tr>
<tr>
<td>Ethanol (control group)</td>
<td>22.4</td>
<td>1.08</td>
<td>1.4x10^{-9}</td>
</tr>
</tbody>
</table>

Compared with ethanol, acetone has a little higher electrical conductivity but lower dielectric constant. With these two changes together, the electric double layer of CNFs is influenced little. As shown in Fig.5.8, the particle’s surface charge in acetone is similar to that in
ethanol, still leading to a metastable state in the range of pH 8~11 and pH 0.25~0.5. But in DMF, the suspension stability is decreased because DMF has much higher dielectric constant and electrical conductivity, making the EDL of CNFs thinner. If using water as the solvent, a stable suspension with high zeta potential (the absolute value > 35 mV) in the range of pH 7~11 can be obtained, and the I.E.P. is decreased to 1.2.

Fig.5.8: Zeta potential profiles of CNFs-COOH (7%) in different solvents.

Fig.5.9 shows the behavior of the zeta potential of CNFs-COOH (7%) with different concentrations in ethanol. It’s noticed that both of the I.E.P. and the global stability (maximum absolute value of zeta potential) are influenced little by the concentration. But the pH range for the stable/metastable suspensions is changed. Below I.E.P., the suspensions with the concentration of 0.5, 1 and 2 mg/mL have the best stability at pH 0.3, 0.9 and 1.4, respectively. The proper pH ranges over I.E.P. for a stable/metastable system with the concentration of 0.5, 1 and 2 mg/mL are pH 9~11, pH 7~11 and pH 5~10, respectively.
Fig. 5.9: Zeta potential profiles of CNFs-COOH (7%) with different concentrations

2) Settling rate

Settling rate cannot only represent the stability of the suspension, but also decide the uniformity of the final deposited layer, especially along the gravity direction. Generally, a suspension for EPD can be divided into three zones: homogeneous zone, settlement zone and supernatant zone. The evolution is shown in Fig. 5.10. In the beginning, a homogenous suspension is prepared with the help of magnetic stirring or ultrasonic dispersion (Fig. 5.10a). If the suspension is stable (|zeta potential| > 35 mV), the homogeneous zone is still dominant after a while of standing. At the same time, a small settlement zone at the bottom and a small supernatant zone on the top are observed. This state can be maintained for a long time (Fig. 5.10b). If the suspension is not stable enough (15 mV < |zeta potential| < 35 mV), the homogeneous zone continually decreases in short-time standing, while the supernatant zone increases (Fig. 5.10c). If the suspension is unstable (|zeta potential| < 15 mV), the homogeneous zone will finally disappear, and there are only settlement zone and supernatant zone left.

In a stable suspension with low solid concentration, the sedimentation process will compete with the electrophoretic mobility during EPD.
The settling rate ($V_s$) can be expressed by the Stokes law \[122\], as shown in Eq. 5.3.

\[ V_s = \frac{2\Delta\rho g r^2}{9\eta} \]  \hspace{1cm} (5.3)

where:
- $\Delta\rho$ = the difference of density between the settled layer and the homogenous suspension;
- $R$ = the particle’s diameter;
- $\eta$ = viscosity of the solvent;

Fig. 5.10: Diagram of the suspension evolution.

And the electrophoretic mobility ($\mu_e$) is related to the zeta potential by the Henry Equation \[123\] (Eq. 5.4).

\[ \mu_e = \frac{2\varepsilon\zeta f(\kappa \cdot a)}{3\eta} \]  \hspace{1cm} (5.4)

where:
- $\varepsilon$ = the dielectric constant of the solvent
- $\zeta$ = zeta potential
η = viscosity of the solvent;

\[ f(\kappa \cdot a) = \text{Henry’s function, } \kappa^{-1} = \text{the Debye length, } a = \text{the particle radius, if } \kappa a \gg 1, \quad f(\kappa \cdot a) = 1.5 \] (Smoluchowski approximation) \[124\]

Combining with Eq.5.3 and 5.4, Eq.5.5 can be obtained:

\[ \frac{V_s}{\mu_e} = \frac{\Delta \rho g r^2}{3 \varepsilon \cdot f(\kappa \cdot a)} \zeta^{-1} \quad 5.5 \]

From Eq.5.5, it’s noticed that the settling rate is inversely proportional to the zeta potential.

It’s difficult to measure the immediate settling rate in my lab; therefore, another parameter related with the settling rate is used to characterize the degree of stability: the relative sediment height (RSH), which can be expressed by Eq.5.6.

\[ \text{RSH(\%)} = \frac{\text{Sediment Height(mm)}}{\text{Total Suspension Height(mm)}} \times \% \quad 5.6 \]

Generally, smaller RSH for a given stable suspension means better stability.

Error always exists when calculating RSH because the boundary between homogeneous zone and settlement zone is not very clear. Therefore, the relative dynamic concentration (C_{rd}) of homogeneous zone is used to decrease the errors. By using syringes, 5-10 mL suspension is extracted from the middle of homogeneous zone. After slowly drying in the vacuum oven, the remnants are weighed by the ultrahigh precision balance and C_{rd} is calculated by Eq.5.7.

\[ C_{rd}(\%) = \frac{\text{Instant Concentration}}{\text{Initial Concentration}} \times \% \quad 5.7 \]

For an unstable system, it makes no sense to calculate RSH or C_{rd} because no one will use an unstable suspension to conduct EPD process.

For a metastable system, RSH/C_{rd} analysis depends on the situation.

Based on the zeta potential results in Part5.3.2, some pH values are chose for preparing metastable/stable CNFs-COOH (7%) suspensions with the concentration of 1 mg/mL in ethanol and water, as shown in Table5.4.

Table5.4: Zeta potential values for CNFs-COOH (7%) in different suspensions

<table>
<thead>
<tr>
<th>Particles</th>
<th>pH</th>
<th>Zeta potential (mV)</th>
<th>State of stability</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td></td>
<td>In ethanol</td>
<td>In water</td>
</tr>
</tbody>
</table>
In ethanol at pH1, the CNFs-COOH has the relatively low zeta potential (20 mV), therefore, as shown in Fig.5.11a, the initial RSH is high (>20%), and the flocculation at the bottom continues to occur, leading to the obvious decrease of RSH in 1 hour. The corresponding $C_{\text{rd}}$ is only 50%, not suitable for EPD process. Other suspensions at pH0.5, pH9, pH10 and pH11 exhibit the increasing stability with the zeta potential of 28 mV, -30 mV, -34 mV, and -36 mV, respectively. Their initial RSH values are lower than 15%, and will change very little in 1 hour.
The remnant concentration of each sample’s homogeneous zone is about 0.35 mg/mL, 0.38 mg/mL, 0.4 mg/mL and 0.45 mg/mL, respectively.

Better stability of CNFs-COOH suspensions can be obtained in water at pH9~11, as shown in Fig5.11b and Table5.5. The dynamic equilibrium between the settlement and homogenous zone can be kept at least 1 hour, and all the C_{rd} values are 90%.

Table5.5: C_{rd} values for CNFs-COOH (7%) in different suspensions.

<table>
<thead>
<tr>
<th>Standing time (h)</th>
<th>C_{rd} (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>Ethanol at pH0.5</td>
</tr>
<tr>
<td>0.25</td>
<td>80</td>
</tr>
<tr>
<td>0.5</td>
<td>75</td>
</tr>
<tr>
<td>1</td>
<td>70</td>
</tr>
<tr>
<td>Water at pH0.5</td>
<td></td>
</tr>
<tr>
<td>0.25</td>
<td>70</td>
</tr>
<tr>
<td>0.5</td>
<td>55</td>
</tr>
<tr>
<td>1</td>
<td>45</td>
</tr>
</tbody>
</table>

Summarizing the above results, the metastable/stable CNFs suspensions listed in Table5.6 can be chose for short-time single-component EPD.

Table5.6: (meta)stable suspensions for CNFs-COOH (7%)

<table>
<thead>
<tr>
<th>Particle</th>
<th>Solvent</th>
<th>pH value</th>
</tr>
</thead>
<tbody>
<tr>
<td>CNFs-COOH (7%)</td>
<td>Ethanol</td>
<td>0.5, 9-11</td>
</tr>
<tr>
<td></td>
<td>Water</td>
<td>9-11</td>
</tr>
</tbody>
</table>

3) Applied voltage

CNFs-COOH(7%) suspensions in ethanol were prepared with a concentration of 0.5 mg/mL, and EPD process was performed at 15-75 V/cm for 10min. After the deposition, the yield of each sample was shown in Fig5.12.

Firstly, higher suspension stability brings higher deposited mass under the same electric field. At pH10, 0.5 and 1.5, the suspension’s zeta potential value is -34 mV, 28 mV and 20 mV,
respectively, and the corresponding maximum deposited mass of 1, 0.8 and 0.6 mg/cm$^2$ can be obtained at 75 V/cm.

![Graph showing deposited mass vs. applied voltage for CNFs-COOH suspension at different pH values.](image)

**Fig.5.12:** Profiles of the deposited mass (versus applied voltage) for CNFs-COOH suspension at different pH values. CNFs concentration: 0.5 mg/mL.

Suspension stability (pH value) also influences the uniformity of the deposited film greatly. If the suspension is not stable enough (pH 1.5, $\delta = 20$ mV), a lot of CNFs prefer settling in the settlement zone to staying in the homogeneous zone. Although a small amount of CNFs can be deposited in the beginning of EPD, there are no enough CNFs for the following growth of the film. Finally, a broken film is obtained, as shown in Fig.5.13a. At pH0.5, the suspension stability is improved a little ($\delta = 28$ mV, $C_{rd, 0.25h} = 80\%$). A film without cracks can be prepared after 10 min EPD (Fig.5.13b), but the surface is uneven, meaning the distribution of CNFs is not uniform. When the suspension is stable (pH 10, $|\delta| = 34$ mV), the concentration of homogeneous zone can keep unchanged for at least 0.5h ($C_{rd, 0.5h} = 90\%$), a uniform CNFs film with smooth surface can be obtained, as shown in Fig.5.13c. Considering the requirement on large-scale production for LIB anode by EPD in the future, the uniformity of the film is a very important precondition. Therefore, the best pH value of CNFs suspension in ethanol for EPD is 10. For the
purpose of dynamics research, other suspensions with different pH values are also chose in this
dissertation.

Secondly, in the same suspension, the deposition mass increase with the applied voltage, but the increasing trend is gradually slowing down. Because of the entanglement of CNFs in the deposited layer, the turbulence effect has little influence on the mass. For a given suspension, applied voltages can also influence surface morphology of the deposited layer greatly. Take the EPD process in a stable suspension at pH10 as the example, if the voltage is too low (30 V/cm), a CNFs film with visible cracks is prepared due to the relatively slow deposition rate (Fig.5.14a). If increasing the voltage to 75 V/cm, although more CNFs are deposited in the same time and the integrity of the film is maintained, some irregularly aggregated CNFs at the surface can be observed. Therefore, the proper applied voltage for EPD in a stable CNFs suspension is around 45 V/cm.

Fig.5.13: Photographs of deposited films on Cu foil after 10 min EPD in ethanol with different pH values: a) pH1.5, b) pH0.5, c) pH10. The applied voltage: 45 V/cm.

Fig.5.14: Photographs of deposited films on Cu foil after 10 min EPD in ethanol at pH10 with the applied voltage of a) 30 V/cm and b) 75 V/cm.

4) Deposition time

Fig.5.15 shows the current changing with time in the voltage range of 30 – 60 V/cm. Firstly, all the current changing profiles have the similar shapes no matter what pH value or
applied voltage is used. It indicates that although pH value and applied voltage can influence the film morphology greatly, they can influence the CNFs deposition mechanism little. The current decreases rapidly in several seconds (<30s), indicating the beginning of the deposition process. Then, the decrease of the current becomes slower, indicating the growth of the CNFs layer. Because CNFs has the good conductivity (~10^6 S/m), the deposited layer wouldn’t influence the substrate’s conductivity too much; therefore, the decrease of the current should be attributed to the irreversibly consumption of the free ions in the solvent. It’s also noticed that the current drop is slower in the acidic suspension (a little water included) than that in the basic suspension under the same electric field. After the formation of an intact film, the current tends to be constant, indicating that less CNFs are deposited with the increasing time due to weaker interaction between CNFs.

![Graph showing current changing with time and applied voltage](image)

**Fig.5.15:** Profiles of current changing in different CNFs-COOH (7%) suspensions with different applied voltages. CNFs concentration: 0.5 mg/mL.

Under the given conditions (applied voltage: 45 V/cm), the relationship between deposition time and the loading per unit area is shown in Fig.5.16. On the one hand, the deposition mass increase with the applied voltage, but the increasing trend is gradually slowing
down. Secondly, on the other hand, with the improvement of suspension stability, more CNFs can be deposited after 15 min EPD. At pH10, 0.5 and 1.5, the suspension’s zeta potential value is -34 mV, 28 mV and 20 mV, respectively, and the corresponding maximum deposited mass of 0.84, 0.62 and 0.42 mg/cm² can be obtained.

![Graph showing deposited mass changing with time in different CNFs-COOH suspensions.](image)

Fig. 5.16: Profiles of deposited mass changing with time in different CNFs-COOH suspensions. CNFs concentration: 0.5 mg/mL.

5) Film morphology and electrochemical properties

![Images showing film morphology and electrochemical properties.](image)

Fig. 5.17: a) photograph of CNFs film (in ethanol, pH10, applied voltage: 45 V/cm); b) SEM image of CNFs film prepared by EPD in ethanol suspension with the concentration of 1 mg/mL.
A typical CNFs film is successfully prepared by 10 min EPD, as shown in Fig. 5.17a. The film is uniform and integrated without any binder. The naked Cu foil margin can be observed because this place is used for the adhesive tape to fix Cu with the stainless steel substrate and no particles can be deposited during EPD. SEM image of the film is shown in Fig. 5.17b. CNFs have the average length of tens of micrometers. They are interweaving rather than bunched up together to form a net-structure on the Cu surface, indicating a homogeneous deposition process. The voltage profile of CNFs-COOH vs. Li with a voltage range of 0.01-3 V at a current density of 400 mAh/g is showed in Fig. 5.18a. The 1st discharge and charge capacities are 328 and 277 mAh/g, respectively, indicating an initial coulombic efficiency (ICE) of 85%. The formation of SEI should be responsible for the irreversible capacity loss. During the following cycles, all the voltage profiles exhibit the similar lithiation/delithiation platform and similar charge/discharge capacity. The cycling performance of the CNFs-COOH film is showed in Fig. 5.18b. It still retains a reversible charge capacity of 280 mAh/g after 100 cycles and the coulombic efficiency almost keeps 100% after the first several cycles.
5.3.3 EPD of Si nanoparticles

1) Zeta potential
Generally, each commercial Si nanoparticle (c-SiNP) has a thin SiO$_2$ layer on the surface, thus a little –OH groups in the solvent can be absorbed, leading to the protonation or deprotonation process depending on the pH value.

In the neutral non-aqueous suspension, an ethanol molecular can ionize and form an alkoxide ion, as shown in Eq.5.8.

$$\text{C}_2\text{H}_5\text{OH} + \text{C}_2\text{H}_5\text{O}-\text{H} \leftrightarrow \text{C}_2\text{H}_5\text{O}^- + \text{C}_2\text{H}_5\text{OH}_2^+ \quad 5.8$$

If the pH value equals to the isoelectric point (I.E.P) value, c-SiNPs have no surface charge. If lower than the I.E.P value, excessive H$^+$ leads to the positive-charged surface with the positive zeta potential (protonation), and the reaction is expressed by Eq.5.9.

$$\text{Si-OH} + \text{H}^+ \xleftarrow{\text{lower than I.E.P.}} \text{Si-OH}_2^+ \quad 5.9$$

If higher than the I.E.P value, the negative-charged surface can be obtained (deprotonation), and the equation is listed as Eq.5.10.

$$\text{Si-OH} + \text{OH} \xrightarrow{\text{higher than I.E.P.}} \text{Si-O}^- + \text{H}_2\text{O} \quad 5.10$$

![Graph showing zeta potential of c-SiNPs in ethanol at different pH values](image)

Fig.5.19: Profile of zeta potential of c-SiNPs in ethanol at different pH values (Si concentration: 0.2 mg/mL).

Fig.5.19 shows the I.E.P. value of c-SiNPs in ethanol is about 3.1, which is higher than the values reported in the literature for pure SiO$_2$ particles $^{125}$, indicating less –OH groups on
the c-SiNPs surface. The maximum absolute value of zeta potential is obtained at around pH2 or pH10, but still very small (<15 mV), meaning that preparing a stable or metastable suspension of c-SiNPs in ethanol is impossible if only adjusting the pH value. Moreover, in the strong acidic condition, the absolute zeta potential value will decrease rapidly because the excessive cations/anions compress the particle’s EDL. In the strong alkali condition, Si can react with OH\(^-\) and finally form silicate ions (Eq.5.11), leading to the decrease of the zeta potential value.

\[
\text{Si} + 2\text{OH}^- + \text{H}_2\text{O} \rightarrow \text{SiO}_3^{2-} + 2\text{H}_2\text{↑}
\]

Fig.5.20: Profiles of zeta potential values for c-SiNPs in different suspensions (Si concentration: 0.2 mg/mL).

As shown in Fig.5.20, c-SiNPs have almost exactly the same profile of zeta potential in acetone as that in ethanol. If ethanol is replaced by DMF, which has much higher dielectric constant and electrical conductivity, the double layer of Si becomes thinner. Therefore, more particles collision and aggregation occurs and the absolute values of zeta potential become smaller throughout the entire pH range. In aqueous suspension, its stability is relatively improved. For pH values below I.E.P., the maximum absolute value of zeta potential is about 22 mV (around pH 2.1). For pH values above I.E.P., especially under the basic condition, the suspension can keep the metastable state, and the maximum zeta potential value is -32 mV at around pH
10.5. However, no matter what kind of solvent is used, a stable Si suspension (|zeta potential|>35 mV) cannot be prepared without any additives.

The influence of SiNPs concentration in ethanol on zeta potential is shown in Fig.5.21. Either I.E.P. or zeta potential value changes little in the range of 0.2 – 0.8 mg/mL, meaning no obvious interaction between Si particles in ethanol.

![Fig.5.21: Profiles of zeta potential of c-SiNPs in ethanol with different concentrations.](image)

2) Settling rate

As mentioned before, preparing a stable or metastable suspension of c-SiNPs in ethanol is impossible if adjusting pH value only. As shown in Fig.5.22, if magnetic stirring is stopped, the homogeneous zone will decrease rapidly and finally disappear in 15 min. No stable homogenous zone means preparing a uniform SiNPs film onto the Cu foil in ethanol by simple EPD is impossible. SiNP surface modification or proper surfactants in the suspension are needed, which will be discussed later.
Fig. 5.22: Photographs of c-SiNPs suspension in ethanol (0.2 mg/mL) a) without standing, b) with 15 min standing. pH value: 10.

5.4 Multi-component EPD for simple Si/CNFs-COOH system

1) Zeta potential

Fig. 5.23: Profiles of zeta potential in different suspensions (pH range: 0.5 – 11, CNFs concentration: 0.5 mg/mL, Si concentration: 0.2 mg/mL).
Compared with CNFs-COOH suspension, c-Si/CNFs-COOH suspension shows the highly similar zeta potential profile (Fig.5.23). Si particles just have a little influence on CNFs stability. Because c-Si has higher I.E.P. values (3.1) than that of CNFs-COOH in ethanol (2.1), it has the same surface charges as CNFs-COOH at the pH range of 11 - 3.1 and 0.5 – 2.1, which is equivalent to increase the density of CNFs’ surface charges and leads to better stability.

If improving Si concentration unilaterally, the influence of Si on the stability of suspension becomes more visible, as shown in Fig.5.24. When Si concentration is lower than 0.4 mg/mL, it’s beneficial to improve the suspension stability at pH 0.5 – 1 or 5 – 11. But if Si concentration is too high (0.8 mg/mL), the serious aggregation of Si particles can also accelerates the sedimentation of CNFs, and the zeta potential values are decreased.

Fig.5.24: Profiles of zeta potential in c-Si/CNFs-COOH suspensions with different Si contents (CNFs concentration: 0.5 mg/mL).

Fig.5.25 shows the influence of total concentration on suspension stability. Generally, higher concentration leads to higher stability at pH1 and pH4 – 9. But in the strong acid or strong alkaline suspension, high concentration and excessive charges means the decrease of particle’s EDL size and suspension stability.
Fig. 5.25: Profiles of zeta potential in c-Si/CNFs-COOH suspension with different total concentrations (weight ratio of CNFs to Si = 5/2)

2) Settling rate

Based on the zeta potential analysis, some pH values are chose for preparing metastable/stable c-Si/CNFs-COOH suspensions in ethanol, as shown in Table 5.7.

Table 5.7: Zeta potential values for c-Si/CNFs-COOH in ethanol at different pH values

<table>
<thead>
<tr>
<th>Particles</th>
<th>pH</th>
<th>Zeta potential (mV)</th>
<th>State of stability</th>
</tr>
</thead>
<tbody>
<tr>
<td>c-Si/CNFs-COOH(7%) (0.4 mg/mL + 1 mg/mL)</td>
<td>1</td>
<td>34.4</td>
<td></td>
</tr>
<tr>
<td></td>
<td>9</td>
<td>-35.6</td>
<td></td>
</tr>
<tr>
<td></td>
<td>10</td>
<td>-36.7</td>
<td></td>
</tr>
</tbody>
</table>
Because of the relatively high zeta potential values at pH1, pH9 and pH10, all the suspensions’ initial RSH values are very low (6%, 5% and 5%, respectively), and increase a little after 4h standing (8%, 7% and 6%, respectively). It’s noticed that the RSH values have no change after 1h standing at pH9 and pH10. The corresponding C_{rd} values are listed in Table5.8. The remnant concentration of each sample’s homogeneous zone at pH1, pH9 and pH 10 is about 1.05 mg/mL, 1.12 mg/mL and 1.2 mg/mL, respectively.

Table5.8: C_{rd} values for c-Si/CNFs-COOH suspensions at different pH values.

<table>
<thead>
<tr>
<th>Standing time (h)</th>
<th>pH1</th>
<th>pH9</th>
<th>pH10</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.25</td>
<td>85</td>
<td>85</td>
<td>90</td>
</tr>
<tr>
<td>0.5</td>
<td>80</td>
<td>85</td>
<td>90</td>
</tr>
<tr>
<td>1</td>
<td>75</td>
<td>80</td>
<td>85</td>
</tr>
</tbody>
</table>

Although the RSH value of the c-Si/CNFs-COOH suspension at pH1 is small and the corresponding C_{rd} value is high, the obvious stratification can be observed after 1h standing, as...
shown in Fig. 5.27. In the single-component system, SiNPs have faster settling rate than CNFs, but in the multi-component system, SiNPs’ settling rate is decreased greatly by the space block of CNFs, while CNFs have faster settling rate. As a result, most CNFs are locating the lower part of the homogeneous zone, leading to non-uniform film in the vertical direction during EPD.

Fig. 5.27: photograph of c-Si/CNFs-COOH suspension at pH1 after 1h standing.

Summarizing the above results, the proper pH range for short-time EPD in c-Si/CNFs-COOH suspensions is 9 – 10 and the best value is 10.

3) Applied voltage

Suspensions consisting of CNFs-COOH and c-Si (0.5 + 0.2 mg/mL, 1 + 0.4 mg/mL) were prepared in ethanol at pH10, and EPD process was performed at 15-75 V/cm for 10min. After the deposition, the yield of each sample was shown in Fig. 5.28.

The composite films have higher deposit density than CNFs film under the same electric field. At 45 V/cm, the deposited mass in the composite suspension with the total concentration of 0.7 mg/mL is 0.92 mg/cm², nearly 10% higher than pure CNFs film (0.84 mg/cm²). If doubling the concentration, the deposited mass increases to 1.12 mg/cm², a little but not double. Similar results are obtained at 75 V/cm. The deposited mass in the composite suspension (0.7 mg/mL) is 1.06 mg/cm², about 10% higher than CNFs film (0.96 mg/cm²), and it increases to 1.28 mg/cm² in the high-concentration composite suspension (1.4 mg/mL). It’s noticed that the increasing trend of deposited mass with the applied voltage in the same suspension becomes slower.
Fig. 5.28: Profiles of the deposited mass (versus applied voltage) for CNFs-COOH suspension at different pH values. CNFs concentration: 0.5 mg/mL.

4) Deposition time and growth mechanism

Fig. 5.29: Profiles of current changing in c-Si/CNFs-COOH suspensions with different applied voltages. Total concentration: 0.5 mg/mL CNFs + 0.2 mg/mL Si.
As shown in Fig. 5.29, the current changing with time in c-Si/CNFs-COOH suspension looks similar to that obtained in CNFs suspension when the applied voltage is not too high (<45 V/cm), indicating little influence of c-Si on the movement of CNFs and deposition. Therefore, the growth of the composite layer should be similar to the growth of CNFs film. SiNPs are randomly deposited along with the growth of CNFs film. If the applied voltage is higher (>45 V/cm), there is a clear distinction between different current changing profiles. After the rapid decrease of the current in the first several seconds (<30 s), the decrease trend in the composite suspension is still high, meaning the obvious increase of the film resistance with deposition time.

Based on the current changing profiles, the possible growth mechanism of c-Si/CNFs-COOH film is shown in Fig. 5.30. In the composite suspension at pH 10, CNFs are dispersed well and keep stable in short time standing (<1h). Influenced by the space effect of CNFs, the settling rate of SiNPs slows down and SiNPs are locating around CNFs. Each Si nanoparticle doesn’t have enough functional groups (-OH) on the surface, so it’s hard to avoid the aggregation of SiNPs during standing or deposition process. If a low electric field is applied (low-voltage EPD), CNFs with negative-charged surface in dilute suspension immediately move to the positive electrode. Their surface charges are neutralized when CNFs are close enough to the electrode, and then a loose deposit film is preliminarily formed. During this process, a small amount of SiNPs with negative surface look like riding CNFs coattails, which are deposited around CNFs randomly and have little influence on either CNFs deposition or the film conductivity. As a result, the growth of the composite film is highly same to the growth of CNFs film. As the increase of time, more CNFs are deposited onto the surface of as-deposited film and less free ions in the suspension are left. Finally, an intact film mainly is formed, mainly consisting of CNFs and some aggregated Si particles distributed in the interspace of CNFs.

If a high electric field is applied, the total deposition (movement) rate is quicker. However, the entanglement among long-chain CNFs also becomes serious, leading to more increase of SiNPs deposition rate than that of CNFs. Therefore, more SiNPs but less CNF are deposited at the beginning, forming a poor-conductive layer at the surface of Cu foil and leading to the decrease of current during deposition. As deposition time increasing, the film’s conductivity becomes lower and the inner electric field becomes weaker, making SiNPs’ movement too slow to be deposited, but some CNFs can still be deposited with gravity effect and inertia effect thanks to their size.
Fig. 5.30: Diagram of the growth of the film on Cu foil with different voltages in c-Si/CNFs-COOH suspension.

Fig. 5.31: Profiles of deposited mass changing with time in c-Si/CNFs-COOH suspensions. Total concentration: 0.2 mg/mL (Si) + 0.5 mg/mL (C).

At 45 V/cm, the relationship between deposition time and the loading per unit area is shown in Fig. 5.31. Compared with CNFs film, the c-Si/CNFs-COOH composite film has higher...
deposited mass under the same conditions. The deposited mass also increases with the deposition time, but the increasing trend are gradually slowing down. After 10 min EPD and 15 min EPD, the deposition density of 0.83 and 0.92 mg/cm$^2$ can be obtained.

5) Morphology and electrochemical properties

![Composite film](image)

Fig.5.32: a) photograph of a composite film on Cu foil (4 × 3.5 cm$^2$). EPD conditions: suspension concentration: 0.5 mg/mL CNFs-COOH + 0.2 mg/mL c-Si; pH = 10; applied voltage: 45 V/cm; Deposition time: 10 min. b) SEM image of the composite film.

![Composite film](image)

Fig.5.33: a) photograph of a composite film on Cu foil (4 × 3.5 cm$^2$). EPD conditions: suspension concentration: 0.5 mg/mL CNFs-COOH + 0.2 mg/mL c-Si; pH = 10; applied voltage: 60 V/cm; Deposition time: 10 min. b) SEM image of the composite film.

A c-Si/CNFs-COOH composite film is prepared by homogeneous EPD in ethanol, as shown in Fig.5.32a. The film is uniform with smooth surface, and no crack can be observed. The SEM image (Fig.5.30b) shows CNFs intertwist with each other to fabricate a continuous conductive skeleton for the anode. SiNPs aggregation is serious and most particles are
distributed randomly among the interspace of CNFs. The thickness of the film (insert in Fig.5.32b) is about 25 μm.

Based on the growth mechanism analysis, the applied voltage has great influence on the structure and morphology of the composite film. As shown in Fig.5.33a, an integrated composite film can be also obtained under the high electric field, but its surface becomes rough and some pores are on it, which is related to the hydrolysis reaction of trace water in the suspension. This reaction becomes more serious with high applied voltage, and a large number of H₂ bubbles appear at the surface of positive electrode, producing some pores during the growth of the film. Fig.5.33b is a SEM image of the pore wall, exhibiting non-uniform distribution of CNFs and SiNPs in the vertical direction. At the bottom of the film, plenty of SiNPs are deposited with very few CNFs skeleton. In the middle, aggregated SiNPs are locating in the CNFs net. On the top, only CNFs can be observed and few SiNPs are deposited.

The voltage profile of c-Si/CNFs-COOH vs. Li with a voltage range of 0.01-3 V at a current density of 400 mAh/g is showed in Fig.5.34a. The 1st discharge and charge capacities are 990 and 620 mAh/g, respectively, indicating an initial coulombic efficiency (ICE) of 63%. The formation of SEI should be responsible for the irreversible capacity loss. High platform at 2.2 V during the first discharging should be caused by the lithiation of CuOₓ [126]. During the following cycles, all the voltage profiles exhibit the similar lithiation/delithiation platform.
Fig. 5.34: Galvanostatic discharge-charge curves for the CNFs/Si composite film; b) cycling performance of the Si/CNFs composite film.

The cycling performance of the CNFs-COOH film is showed in Fig 5.34b. After the first cycle, the discharge and charge capacities rapidly decrease to 580 and 530 mAh/g in the second cycle, respectively; then increase slowly to 870 and 790 mAh/g in 18 cycles. During the following cycles, the discharge/charge capacities drop slowly again. After 100 cycles, the
discharge capacity of 610 mAh/g can be obtained. This variation tendency indicates the gradual activation of SiNPs in the composite film. Because the inner aggregated SiNPs have no enough contact with CNFs, not all the SiNPs can be lithiated in the short time. Some new SiNPs are continuously exposed during cycles, leading to unstable SEI layer and irreversible consumption of Si anode. Fig.5.35 shows the surface morphology of the composite film after 50 cycles. A large number of cracks on the top can be observed. Therefore, the coulombic efficiency is only about 90% during cycles.

![SEM image of the film after 50 cycles](image)

Fig.5.35: SEM image of the film after 50 cycles

Based on the structure features of Si/CNFs films, either increasing the applied voltage or improving Si content can cause worse electrochemical properties. Fig.5.36 shows the influence of high voltage on cycling performance. The 1\textsuperscript{st} discharge and charge capacity are 239 mAh/g and 169 mAh/g, respectively, and the ICE is about 69%. In the following cycles, the composite even exhibits lower capacity (<180 mAh/g) than that of pure CNFs (Fig.5.18b). Such bad electrochemical property is mainly caused by the composite microstructure feature (Fig.5.33a). The Si layer locating at the bottom of the composite film cannot only prohibit the electron/Li\textsuperscript{+} transfer during charging/discharging process, but also has huge volume effect to weaken the adhesive force with Cu foil. As a result, little SiNPs are activated during cycles, which have negative effect on the lithiation/delithiation process of CNFs and lead to low capacity.
Fig. 5.36: cycling performance of the composite film prepared under high electric filed (75 V/cm) at the current rate of 400 mA/g.

As shown in Fig. 5.37, if improving the initial Si concentration from 0.2 mg/mL to 0.4 mg/mL, Si aggregation become much more serious, and CNFs net has little effect on inhibiting the breakage of the structure, leading to the rapid decrease of the cycle performance of the film (Fig. 5.37b).

Fig. 5.37: a) SEM image of the Si/CNFs film with high Si content; b) the corresponding cycle performance at the current rate of 400 mA/g.
5.5 Summary

In this chapter, the stability of Si/CNFs suspensions and their deposition dynamics during multi-component EPD were studied systematically. Si/CNFs composite films without any binder were prepared in proper suspensions by multi-component EPD. The results show:

1) EPD of CNFs

The stability of CNFs suspension in ethanol was improved after the introduction of –COOH by acid refluxing method. In ethanol at pH 9 ~ 11 and pH 0.5, CNFs-COOH suspensions with the concentration of 0.5 mg/mL have relatively high zeta potential value (>25 mV), which can keep stable in a short time (<1h). If considering the influence of pH value on the uniformity and the integrity of the final deposited film, the suspension at pH10 is the best choice for short-time EPD. Higher concentration (<2 mg/mL) makes the suspension more stable but cannot make the deposited mass increasing proportionately. The deposited mass increases with the applied voltage and deposition time. However, the growth rate of the film slows down as the increase of the deposition time and excessive voltage (>60 V/cm) can lead to serious aggregation of CNFs on the film surface. The proper voltage for EPD of CNFs is around 45 V/cm and the time is around 10 ~15 min. Under such conditions, a uniform and dense CNFs film with the maximum deposition density of 0.84 mg/cm² can be obtained.

2) EPD of Si/CNFs

Although Si suspensions in ethanol at pH 0.5 – 11 are not stable, stable Si/CNFs suspensions can be prepared in ethanol at pH 9 ~ 10 because a small amount of SiNPs (< 0.8 mg/mL) have little influence on CNFs surface charge (0.5 mg/mL) and their settlement can be inhibited by the space effect of CNFs, making the multi-component EPD possible. The deposited mass of the Si/CNFs film increases with the deposition time and applied voltage. If the applied voltage is low (< 60 V/cm), SiNPs deposition and CNFs deposition are relatively independent. If the voltage is higher than 60 V/cm, the porous structure of the composite film is formed due to the turbulence effect, and more bulk SiNPs are deposited at the bottom with improved deposition rate. Therefore, the optimal conditions for preparing uniform and dense Si/CNFs films by EPD are using the composite suspension at pH10 with the external electric field of 45 V/cm. After 15 min deposition, the deposited mass of 0.92 mg/cm² can be obtained.
3) Preparation of Si/CNFs films with improved electrochemical properties by multicomponent EPD

A uniform Si/CNFs composite with the thickness of 25 um was prepared in ethanol at pH10 by 10-min multicomponent EPD. The initial weight ratio of Si to CNFs is 2/5. CNFs fabricate the continuous conductive net, while the aggregated SiNPs are randomly distributed in it. The deposited mass is about 0.83 mg/cm². The film exhibits good cycle performance with the capacity of 610 mAh/g after 100 cycles, but the corresponding Coulombic efficiency is only 90%, meaning SiNPs distribution should be improved further to make SEI layer more stable during cycles.
Chapter 6

MULTI-COMPONENT EPD OF MODIFIED-Si/CNFs COMPOSITION ANODE FOR LIB

6.1 Introduction

As the future demands on power and energy density in the field of portable device and electric vehicle increase, lighter, smaller, and long-lasting LIB is needed. Si is the most promising anode material with a theoretical specific capacity of 4,200 mAh/g. However, pure Si anode is still far away from commercialization due to poor conductivity and huge volume change during cycles.

The most popular way to achieve the use of Si in LIB is introducing carbonaceous materials into Si-based anode. A large number of Si/C composite materials have been prepared (Chapter 2.3). Besides the introduction of C, some functional groups have been also introduced onto Si surface via surface modification to enhance the physical contact between Si and C \[^{127 - 128}\], which greatly increase the anode cycle life.

More importantly, the functional groups can directly influence the stability of Si-containing suspension via influencing the EDL of Si, and leads to different mobility rates and deposition rates of Si during EPD. Therefore, the surface modification of Si is beneficial to the design of microstructure of C/Si composite and EPD dynamics analysis.

In this section, based on the results in Part 3, some Si/CNFs composite films with specific microstructures are prepared by EPD. The influence of Si surface modification on suspension stability, film growth and morphology are studied. The electrochemical properties of films with different Si particles are analyzed.

6.2 Structural design and experiment

6.2.1 Structural design

CNFs and commercial Si nanoparticles (SiNPs) were chose as the raw materials.

There are two main problems for the c-Si/CNFs-COOH composite films prepared in Part 3: 1) no strong link between CNFs and SiNPs; 2) serious Si aggregation. During
charging/discharging cycles, although the integrity of the film can be maintained well, inner SiNPs easily lose the electrical contact with CNFs. Meanwhile, no stable SEI layer is formed in many same areas. Therefore, this part mainly focuses on Si distribution and interaction between CNFs and SiNPs.

Two objectives should be achieved in this section.

Firstly, different functional groups such as hydroxyl (-OH)\textsuperscript{[129]} or amino (-NH\textsubscript{2})\textsuperscript{[130]} would be introduced onto Si surface, and each modification method has the positive influence on the stability of suspension and the film quality after EPD. The requirement on the method of Si surface modification is simple and efficient.

Secondly, several composite films with specific microstructures would be prepared by EPD with the help of Si surface modification. The microstructure depends on the experimental conditions, and has at least one feature as follow: 1) well distribution of Si in the CNFs net and no serious aggregation; 2) strong interaction between Si and CNFs during EPD. The electrochemical properties of these films, such as specific capacity, ICE or cycle life, should be improved a lot.

6.2.2 Experiment
The steps are listed as follow.

1) Hydroxylation of SiNPs (Si-OH)\textsuperscript{[129]}. SiNPs were firstly immersed into HF solution for 0.5h, then refluxed in the piranha solution (1:2 v/v H\textsubscript{2}SO\textsubscript{4}: H\textsubscript{2}O\textsubscript{2}) for 30min at 80\textdegree C. In the end, they were washed to neutral by deionized water and dried in vacuum oven for 3h at 100\textdegree C.

2) Amination of SiNPs (Si-NH\textsubscript{2})\textsuperscript{[130]}. After the hydroxylation of SiNPs, the particles are immediately transferred into the mixture of APTES and ethanol (1:15 v/v). After 3h, all the particles were took out and rinsed by ethanol to remove the excessive APTES. In the end, they were dried in a vacuum oven for 3h at 100\textdegree C.

3) Preparation of suspensions. The mixture of modified-Si/CNFs-COOH with different weight ratios were dispersed into 50 mL ethanol followed by ultrasonication for 2h. LiOH and HCl were used to adjust the corresponding pH value of 1~11. Different surfactants and electrolyte additives were also used to improve the stability of suspensions.

4) Zeta potential measurement and EPD procedures. See Chapter4.
6.3 Surface modification of SiNPs

Si nanoparticles (SiNPs) have the average size of 50~100 nm, as shown in Fig. 6.1a, and the surface treatment didn’t change the size or morphology of SiNPs, as shown in Fig. 6.1b and c.

Fig. 6.1: SEM images of a) c-SiNPs, b) Si-OH particles and c) Si-NH₂ particles.

Fig. 6.2: FTIR spectra of SiNPs before and after surface modification

Fig. 6.2 shows the FTIR spectra of SiNPs and modified-Si, and the corresponding absorption peaks are summarized in Table 6.1. For SiNPs, a strong Si-O-Si stretching peak at 1080 cm⁻¹ is observed, indicating the presence of SiO₂ layer on the surface. It’s noticed that this peak is almost unchanged after surface treatment, meaning the modification indeed occur at the
The peak at 1620 cm\(^{-1}\) can be assigned to –OH bending vibration from the physically absorbed water. For Si-OH, a new peak at 820 cm\(^{-1}\) corresponding to the Si-OH groups can be observed, confirming the successful introduction of –OH groups. For Si-NH\(_2\), the new peaks at 690 cm\(^{-1}\) and 2890 cm\(^{-1}\) are attributed to Si-C and –CH\(_2\) groups from the residual APTMS, respectively. The peak at 1480 cm\(^{-1}\) is attributed to the deformation vibration of -NH\(_2\) groups. The peaks at 3200 cm\(^{-1}\) corresponding to NH\(_2\) stretching vibration is not obvious because it overlaps with –OH stretching vibrations.

Table 6.1: Assignment of infrared absorptions for SiNPs and modified-Si.

<table>
<thead>
<tr>
<th>Assignment</th>
<th>Wavenumber (literature(^{[131]})) (cm(^{-1}))</th>
<th>Wavenumber (experiment) (cm(^{-1}))</th>
<th>Wavenumber (experiment) (cm(^{-1}))</th>
</tr>
</thead>
<tbody>
<tr>
<td>-CH(_2)</td>
<td>2850 – 2945</td>
<td>2890</td>
<td>-</td>
</tr>
<tr>
<td>O-H bending</td>
<td>1600 – 1630</td>
<td>1600</td>
<td>1620</td>
</tr>
<tr>
<td>N-H deformation</td>
<td>1430 – 1500</td>
<td>1480</td>
<td>-</td>
</tr>
<tr>
<td>Si-O-Si</td>
<td>1010 – 1190</td>
<td>1020</td>
<td>1080</td>
</tr>
<tr>
<td>Si-OH</td>
<td>800 – 900</td>
<td>800</td>
<td>820</td>
</tr>
<tr>
<td>Si-C</td>
<td>670 – 760</td>
<td>690</td>
<td>-</td>
</tr>
</tbody>
</table>

Fig. 6.3: XPS spectra of c-SiNPs
Fig. 6.3 shows the XPS spectra of the pristine SiNPs, confirming the presence of a SiO$_2$ layer on the surface. Concerning Si 2p spectrum firstly (Fig. 6.3a), three peaks can be observed: one at ~99.3 eV corresponding to the bulk Si, another one at ~102.3 eV corresponding to Si-O-H, and the last one at ~104.3 eV corresponding to SiO$_2$. After 10 min Ar sputtering treatment, the peak at ~99.3 eV becomes much stronger but the peak at ~104.3 eV disappears, meaning the silica layer is removed. From O 1s spectrum (Fig. 6.3b), it’s also noticed that the peak at ~533.7 eV assigned to SiO$_2$ disappears after 10 min sputtering.

Fig. 6.4 shows the XPS spectra of Si-OH and Si-NH$_2$. Firstly, the SiO$_2$ layer will be removed by HF etching method before surface modification, so only one peak at ~99 eV attributed to bulk Si can be observed (Fig. 6.4a and 6.4c). After the introduction of –OH groups, the peak at ~102.3 eV from Si 2p spectrum (Fig. 6.4a) and the peak at ~533.6 eV from O 1s
spectrum (Fig.6.4b) can be observed, which is assigned to Si-OH and –OH groups, respectively. Besides, SiO₂ is re-formed on the surface (the peak at ~103.6 eV). After sputtering treatment, the peaks related to Si-O-H and SiO₂ are weakened or disappear, indicating the modification reaction is limited to the surface area only. As shown in Fig.6.4c, after the introduction of –NH₂ groups, the peak at 101.8 eV assigned to Si-N-H can be observed but the peak corresponding to bulk Si disappears, indicating all the surface SiNPs react with APTMS to form the –Si-N- bond. The peak at ~ 398.2 eV from N 1s spectrum (Fig.6.4d) corresponding to NH₂ can be also observed. After 10 min sputtering, both of the peak at 101.8 eV and the peak at 398.2 eV become weaker and wider, and the inner Si is exposed again (the peak at 98.7 eV).

6.4 EPD of modified-SiNPs

1) Zeta potential

![Zeta potential profile graph](image)

Fig.6.5: Zeta potential profiles of different Si particles in ethanol

On the one hand, the I.E.P. value is changed after introducing functional groups. Compared with c-SiNPs, Si-OH has lower I.E.P. value (2.1) because of more –OH dissociation. In theory, a particle with -NH₂ group should have the I.E.P. value of higher 7 because of –NH₂ dissociation;
however, there may be some remaining –OH groups locating on the Si–NH₂ surface. Due to the synergistic effect, Si-NH₂ has the I.E.P. value of 5.3, higher than other samples. On the other hand, both Si-OH and Si–NH₂ suspensions show better stability than c-SiNPs in ethanol. For Si-OH suspension, the maximum absolute value of zeta potential is about 21 mV at pH 1.4 and 28 mV at pH 10.2, respectively. And the metastable zone in basic condition seems wider than that in acidic condition. For Si–NH₂ suspension, the maximum absolute value is similar to that in Si-OH suspension, about 25 mV at pH 2.4 and 24 mV at pH 11, respectively, but the metastable zone in acidic condition is wider than that in basic condition. Unluckily, like c-SiNPs, no matter what pH value is, no stable Si suspension with higher zeta potential (>35 mV) can be obtained even after surface treatment.

If using water as the solvent, a stable suspension with high zeta potential (>35mV) can be obtained by adjusting pH value, as shown in Fig.6.6. For Si-OH, the proper pH value is 1.5 ~ 1.8 and 8.5 ~ 9.5; For Si-NH₂, the proper pH value is 1.5 ~ 2.5 and 9 ~ 11.

Fig.6.6: Zeta potential profiles of different Si particles in water

Fig.6.7 shows the zeta potential profiles of Si-OH in different organic solvents. Compared with ethanol system, the particle behavior changes little in acetone, while becomes less stable in DMF. The same results can be obtained in different Si-NH₂ suspensions, as shown
in Fig.6.8. It’s still very hard to prepare a stable suspension for modified-Si in organic solvents without any stabilizer.

Fig.6.7: Zeta potential profiles of Si-OH suspension in different organic solvents

Fig.6.8: Zeta potential profiles of Si-NH₂ suspension in different organic solvents
Similar to c-SiNPs system, if the suspension of modified-Si has low concentrations (<0.8 mg/mL), the changes of particle concentration has little impact on zeta potential distribution throughout the entire pH range, as shown in Fig.6.9.

![Zeta potential profiles of Si suspension in ethanol with different concentrations](image)

Fig.6.9: Zeta potential profiles of Si suspension in ethanol with different concentrations

Besides, in the most cases, the absolute value of zeta potential is decreased in the strong alkaline suspension, especially for Si-OH, which is caused by the reaction between Si and free OH\(^-\) in ethanol (Eq.5.11).

1) Settling rate

It only makes sense for stable or metastable suspension to discuss the settling rate, therefore, based on the zeta potential profiles, some specific pH values are chose for Si-OH and Si-NH\(_2\), respectively, as shown in Table.6.2.

Table.6.2: Zeta potential values for Si-OH and Si-NH\(_2\) in different suspensions

<table>
<thead>
<tr>
<th>Particles</th>
<th>pH</th>
<th>Zeta potential (mV)</th>
<th>State of stability</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>In ethanol</td>
<td>In water</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Si-OH</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>20</td>
<td>39</td>
<td></td>
</tr>
<tr>
<td>8</td>
<td>19</td>
<td>36</td>
<td></td>
</tr>
<tr>
<td>9</td>
<td>24</td>
<td>40</td>
<td></td>
</tr>
</tbody>
</table>
The RSH profile can better describe the difference of stability between metastable suspensions than zeta potential, as shown in Fig. 6.10. Firstly, for each metastable Si-OH suspension in ethanol, the initial RSH is high (>10%) and will decrease with the increase of standing time, implying no balance state between the homogeneous zone and settlement zone. At pH1, pH8 or pH9, the RSH decreases rapidly even in the beginning. Combining with the related \( C_{rd} \) values (Table 6.3), a serious flocculation of Si-OH should occur continuously at the bottom. The initial Si-OH concentration in the homogeneous zone is 0.4 mg/mL. After 1h standing, all the remnant concentrations at pH1, pH8 and pH9 are less than 0.25 mg/mL. At pH10, the stability is a little improved, \( C_{rd} \) still decreases with the standing time at a relative slow rate, equaling to 70% after 1h.

![Fig. 6.10: Profiles of RSH value versus standing time for Si-OH suspensions at different pH values in ethanol.](image)

Table 6.3: \( C_{rd} \) values for Si-OH suspension in ethanol.
<table>
<thead>
<tr>
<th>Standing time (h)</th>
<th>Suspension at pH1</th>
<th>Suspension at pH8</th>
<th>Suspension at pH9</th>
<th>Suspension at pH10</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.25</td>
<td>70</td>
<td>65</td>
<td>75</td>
<td>80</td>
</tr>
<tr>
<td>0.5</td>
<td>55</td>
<td>55</td>
<td>60</td>
<td>75</td>
</tr>
<tr>
<td>1</td>
<td>45</td>
<td>40</td>
<td>55</td>
<td>70</td>
</tr>
</tbody>
</table>

However, for Si-NH₂ suspensions in ethanol, all of them prefer to the unstable state. As shown in Fig6.11 and Table6.4, both of RSH and $C_{rd}$ values change greatly for each sample in one hour, and the concentration of the homogeneous zone decreases by at least 45%. If increasing the standing time (>2h), the RSH values tend to be stable, meaning the possibility for short-time EPD in the homogeneous zone, but $C_{rd}$ values may be too low (<50%) to obtain the dense deposited film with high loading.

![Graph](image-url)

**Fig.6.11:** Profiles of RSH value versus standing time for Si-NH₂ suspensions at different pH values in ethanol.

**Table6.4:** $C_{rd}$ values for Si-NH₂ suspension in ethanol
<table>
<thead>
<tr>
<th>Standing time (h)</th>
<th>C_{rd} (%)</th>
<th>Suspension at pH1.5</th>
<th>Suspension at pH2</th>
<th>Suspension at pH3</th>
<th>Suspension at pH10</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.25</td>
<td>70</td>
<td>75</td>
<td>65</td>
<td>70</td>
<td></td>
</tr>
<tr>
<td>0.5</td>
<td>60</td>
<td>65</td>
<td>50</td>
<td>60</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>50</td>
<td>55</td>
<td>40</td>
<td>55</td>
<td></td>
</tr>
</tbody>
</table>

Generally, the range of zeta potential (absolute value) for a metastable suspension is 15 ~ 35 mV, but based on the settling rate test, only those with higher zeta potential (absolute value) than 25 mV can be used for the short-time EPD when the standing time is less than 1h. This conclusion can be further confirmed in the stable aqueous suspension of Si-OH or Si-NH$_2$.

For the Si-OH aqueous suspensions at pH1 and pH9, they seem very stable with small initial RSH values (<10), as shown in Fig.6.12. With the increase of standing time, the RSH even increases a little and then keeps unchanged, indicating the long-time stability. From Table6.5, it shows more particles can stay in the homogeneous zone in 1h if the suspension is stable (|zeta potential|>35 mV). The corresponding C_{rd} values are 80%, 75% and 85% at pH 1, pH 8 and pH 9, respectively. The similar results can be obtained for Si-NH$_2$ aqueous suspensions, as shown in Fig.6.13 and Table6.6. In the most stable suspension (at pH10), the initial RSH value is about 5%, and the C_{rd} value is a constant (90%) in one hour.
Fig. 6.12: Profiles of RSH value versus standing time for Si-OH suspensions in water.

Table 6.5: C_{rd} values for Si-OH suspension in water

<table>
<thead>
<tr>
<th>Standing time (h)</th>
<th>Suspension at pH1</th>
<th>Suspension at pH8</th>
<th>Suspension at pH9</th>
<th>Suspension at pH10</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.25</td>
<td>80</td>
<td>80</td>
<td>85</td>
<td>80</td>
</tr>
<tr>
<td>0.5</td>
<td>80</td>
<td>75</td>
<td>85</td>
<td>75</td>
</tr>
<tr>
<td>1</td>
<td>80</td>
<td>75</td>
<td>85</td>
<td>60</td>
</tr>
</tbody>
</table>
Fig. 6.13: Profiles of RSH value versus standing time for Si-NH$_2$ suspensions in water.

Table 6.6: $C_{rd}$ values for Si-NH$_2$ suspension in water

<table>
<thead>
<tr>
<th>Standing time (h)</th>
<th>$C_{rd}$ (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>Suspension at pH1.5</td>
</tr>
<tr>
<td>0.25</td>
<td>85</td>
</tr>
<tr>
<td>0.5</td>
<td>80</td>
</tr>
<tr>
<td>1</td>
<td>80</td>
</tr>
</tbody>
</table>

Overall, if the deposition time is less than 0.5h, some metastable/stable suspensions for modified-Si particles listed in Table 6.7 can be used for single-component EPD.

Table 6.7: pH range for single-component EPD process.

<table>
<thead>
<tr>
<th>Particle</th>
<th>Solvent</th>
<th>pH value</th>
</tr>
</thead>
<tbody>
<tr>
<td>c-SiOH</td>
<td>Ethanol</td>
<td>10</td>
</tr>
<tr>
<td></td>
<td>Water</td>
<td>1, 8–10</td>
</tr>
<tr>
<td>c-SiNH$_2$</td>
<td>Ethanol</td>
<td>None</td>
</tr>
</tbody>
</table>
2) Applied Voltage

Si-OH and Si-NH$_2$ Suspensions in ethanol were prepared respectively with a concentration of 0.4 mg/mL, and EPD process was performed at 15 - 75 V/cm for 10min. After the deposition, the yield of each sample was measured, as shown in Fig.6.14 and 6.15.

![Graph showing deposition mass versus applied voltage for Si-OH EPD in ethanol](image)

**Fig.6.14: Profiles of deposited mass versus applied voltage for Si-OH EPD in ethanol**

For Si-OH system (Fig.6.14), the deposition mass increase with the applied voltage (15 – 60 V/cm) and the maximum value of 0.24 mg/cm$^2$ can be obtained at 60V/cm (pH10). However, the increasing trend is gradually slowing down, which is caused by two reasons. Firstly, particles have faster mobility rate at higher voltage so that they don’t have enough time to find the best locations to fabricate a dense structure. Secondly, a stronger electric field leads to faster increase of the ethanol temperature, so the turbulence effect around the substrate becomes more serious, inhibiting the normal deposition process. If the voltage is too high (75 V/cm), a large number of bubbles can be observed near the substrate after 5 min EPD, damaging the deposited layer and leading to the decrease of the deposition mass. Besides, under the same electric field, the
suspension stability can also impact the deposition mass. In a suspension at pH 8, the absolute value of zeta potential decreases from 28 mV to 19 mV, and the maximum value decreases from 0.24 mg to 0.14 mg.

Fig. 6.15: Profiles of the deposited mass versus applied voltage in ethanol for Si-NH₂ EPD (standing time for the suspension: 2h)

For Si-NH₂ system (Fig. 6.15), the changing trend of the deposition mass is similar to that showed in Fig. 6.14 if the suspension is alkaline, and the maximum value is about 0.16 mg. Under the acidic condition, HCl is used to adjust the pH value and a small amount of water is simultaneously introduced. Therefore, the electrolysis of water always accompanies by the deposition process, producing some gas bubbles near the substrate and aggravating the turbulence effect, especially at high voltages (>45 V/cm). As a result, the maximum deposition mass is about 0.14 mg/cm² at 45 V/cm.
Fig. 6.16: a) Current-time profiles and b) electrical conductivity – time profiles in Si-OH suspension (ethanol) with different applied voltages; c) diagram of the movement and deposition of Si-OH in ethanol.

Under a given electric field (30 – 60 V/cm), the current/electrical conductivity changing with time can describe the film-formation process, as shown in Fig.6.16. For each sample, the current/electrical conductivity changing can be divided into three stages. In the first few seconds, the current and electrical conductivity decreases sharply, indicating the start of the deposition of Si-OH on the substrate (Cu) surface (Fig.6.16c stage1). Higher voltage makes more particles deposited in shorter time. Then in the following minutes (~3 – 5 min), the current and electrical conductivity continues to decrease at a moderate rate, indicating the growth of a non-conductive deposited layer (Fig.6.16c stage2). After a thick layer is formed, a few Si particles still move forward to the electrode by the driving of the electric field, and some of them can infiltrate the
layer and stay in the pores or cracks (Fig. 6.16c stage 3). As a result, the deposition mass will increase a little, and the current and electrical conductivity will decrease slowly.

Fig. 6.17 shows the current/electrical conductivity changing with time at different voltages in the Si-NH₂ suspension (pH 1.5). The profile’s changing tendency at 30 V/cm or 45 V/cm is similar to the one discussed in Fig. 6.16, which means the formation of the Si-NH₂ layer also follow the three-stage growth mechanism. Because Si-NH₂ is positive charged in ethanol, the deposition process should occur on the negative electrode. But at 60 V/cm, the second stage is very short (~100s), meaning the growth of the layer is slow. It should be caused by the serious turbulence effect due to the presence of water, which is consistent with the result in Fig. 6.15.

![Fig. 6.17: a) Current-time profiles and b) electrical conductivity – time profiles in Si-NH₂ suspension (ethanol) with different applied voltages.](image)

3) Deposition time

Generally, in a given suspension, the deposition mass increase with the deposition time in the constant voltage mode, which can be described by an empirical equation (Eq. 2.12).

\[
\frac{dY}{dt} = f \mu c ES
\]

where:

- \( Y \) = the yield;
- \( t \) = the deposition time;
- \( \mu \) = the electrophoretic mobility;
- \( E \) = the electric field strength;
- \( c \) = the concentration of the suspension;
- \( S \) = the electrode surface
f = dynamics parameter

Combining with Eq.3.4 (ka>>1), a new equation (6.1) is obtained.

\[ \frac{dY}{dt} = f \frac{\varepsilon \xi c S}{\eta} E \]

6.1

where:

\( \varepsilon \) = the dielectric constant of the solvent
\( \xi \) = zeta potential
\( \eta \) = viscosity of the solvent

In an ideal condition, \( \varepsilon, \xi, \eta \) and E is constant, and c can be also considered as a constant because it’s much larger than the density of the deposited layer, therefore, the yield shows a linear relationship for the deposition time.

But in reality, E is changing constantly during EPD, and sometimes the decrease of c cannot be ignored. Therefore, Eq.6.1 is changed to

\[ \frac{dY}{dt} = k_f Sc(t)E(t) \]

6.2

where:

\( k_f = f \frac{\varepsilon \xi}{\eta} \)

\( c(t) \) = the real-time concentration of the suspension
\( E(t) \) = the real-time electric field strength

The equivalent electric circuit of EPD process is shown in Fig.6.18. Four resistors are connected in series, representing the substrates \( (R_c) \), suspension \( (R_s) \), deposited layer \( (R_d) \), and the external resistance \( (R_0) \). Therefore, E should be written as

\[ E = E_0 + E_s + E_d + E_c = I(R_0 + R_s + R_d + R_c) \]

6.3
Fig. 6.18: The equivalent electric circuit of the EPD cell

In the constant voltage mode, $E$ is a constant (the applied voltage). $R_0$ and $R_c$ changes very little. $R_d$ increases with the time due to the growth of the non-conductive deposited layer.

The real-time electric field strength during EPD can be simply represented by $E_s$

$$E_s = E(t) = I(t)R_s = \frac{I(t)}{\Lambda S} \quad \text{6.4}$$

where:

$\Lambda$ = the conductivity of the suspension,

$I(t)$ = the real-time current

Inserting Eq. 4.4 into Eq. 6.2 gives

$$\frac{dY}{dt} = \frac{k_f}{\Lambda} c(t)I(t) \quad \text{6.5}$$

If the suspension is metastable, $c(t)$ should be influenced by both the settlement process and the deposition process, which can be expressed by Eq. 6.6

$$c(t) = c_0 - c_s(t) - c_d(t) \quad \text{6.6}$$

where:

$c_0$ = the initial concentration of the suspension

$c_s(t)$ = the real-time concentration of the settlement zone

$c_d(t)$ = the real-time concentration of the deposited layer
In a metastable/stable system, the settling rate can be considered as the constant for a while. Therefore, \( c_s(t) \) can be expressed by Eq. 6.7

\[
c_s(t) = k_s t
\]

where:

\[
k_s = v_s = \frac{2\Delta \rho g r^2}{9\eta}
\]

As mentioned before, the initial concentration of Si-OH or Si-NH\(_2\) in ethanol used here is 0.4 mg/mL and the suspension volume is 50 mL, so the total mass of Si particles is 20 mg. The substrate (Cu foil) area is 2×2 cm\(^2\) and the maximum deposited mass (Fig. 6.22 and 6.23) is no more than 0.3 mg/cm\(^2\), indicating less than 1.2 mg of Si are deposited every time. Therefore, the effect of the deposition process on \( c(t) \) can be ignored, and Eq. 6.5 can be simplified

\[
c(t) = c_0 - k_s t
\]

Inserting Eq. 6.8 into Eq. 6.5 gives

\[
\frac{dY}{dt} = \frac{k_f}{\Lambda}(c_0 - k_s t)I(t)
\]

Integrating Eq. 6.9 gives

\[
Y = a \int_0^t I(t) - b \int_0^t I(t) dt
\]

where:

\[
a = \frac{k_f c_0}{\Lambda} \quad \text{(for a given system, a is a constant and is not influenced by the applied voltage or EPD)};
\]

\[
b = \frac{k_f k_s}{\Lambda} \quad \text{(settlement coefficient)}
\]

Therefore, the deposited mass can be estimated by measuring the current changing with the deposition time. Based on the three-stage growth mechanism of the deposited layer (Fig. 6.16), most deposition occurs in the stage 2 and stage 3. To simplify the model, we ignore the deposition of a small amount of particles in the stage 1 and assume the current has a linear relationship with the deposition time in each stage (when \( t > 30s \)):

\[
I(t) = I_0 - At
\]

where:

\( I_0 \) = the initial current as the deposition occurs;
A: the correction coefficient on the electric field.

Inserting Eq.6.12 into 6.11 gives

\[ Y = y_0 + aI_0 t - \frac{1}{2} (I_b + aA)t^2 + \frac{1}{3} Abt^3 \]  \hspace{1cm} 6.13

Eq.6.13 can describe the deposition process of the Si suspension in ethanol for a short time.

For Si-OH system in ethanol, as shown in Fig.6.19, the linear relationship between the current and the deposition time is defined:

Stage 2: \( I = 0.218 - 3.576 \times 10^{-4} t \) \hspace{1cm} \( R^2 = 0.9700 \)  \hspace{1cm} 6.14

Stage 3: \( I = 0.164 - 9.726 \times 10^{-6} t \) \hspace{1cm} \( R^2 = 0.9879 \)  \hspace{1cm} 6.15

And the related parabolic deposition kinetic is:

Stage 2: \( Y = 0.0165 + 0.0995t - 0.0159t^2 + 7.826 \times 10^{-4} t^3 \) \hspace{1cm} \( R^2 = 0.9899 \)  \hspace{1cm} 6.16

Stage 3: \( Y = 0.0931 + 0.0403t - 3.04 \times 10^{-3} t^2 + 7.055 \times 10^{-5} t^3 \) \hspace{1cm} \( R^2 = 0.9917 \)  \hspace{1cm} 6.17

For Si-NH\(_2\) system, as shown in Fig.6.20, the linear relation between the current and the deposition time is:

Stage 2: \( I = 0.253 - 4.018 \times 10^{-4} t \) \hspace{1cm} \( R^2 = 0.9816 \)  \hspace{1cm} 6.18

Stage 3: \( I = 0.170 - 5.672 \times 10^{-4} t \) \hspace{1cm} \( R^2 = 0.9741 \)  \hspace{1cm} 6.19

And the related parabolic deposition kinetic is:

Stage 2: \( Y = 0.0113 + 0.0873t - 0.0213t^2 + 2.17 \times 10^{-3} t^3 \) \hspace{1cm} \( R^2 = 0.9957 \)  \hspace{1cm} 6.20

Stage 3: \( Y = 0.1342 + 0.0032t + 8.9676 \times 10^{-4} t^2 - 4.789 \times 10^{-5} t^3 \) \hspace{1cm} \( R^2 = 0.9833 \)  \hspace{1cm} 6.21

Unlike Eq.6.26, 6.27 and 6.30, Eq.6.31 has the positive square term and the negative cubic term, indicating \( b < 0 \). It should be related to the turbulence effect. Although the applied voltage is not too high, the electrolysis of the water becomes serious in the acidic condition as the increase the deposition time and the ethanol will be also heated. Therefore, more bubbles are generated. They peel off particles from the deposited layer and making the re-mixture of particles between the homogenous zone and the settlement zone. As a result, the real-time concentration near the substrate may even be bigger than that in settlement zone, leading to the negative \( k_s \) and \( b \).
Fig. 6.19: Profiles of a) current versus time and deposited mass versus time in Si-OH suspension.
Fig. 6.20: Profiles of a) current versus time and deposited mass versus time in Si-NH₂ suspension
6.5 EPD of modified-Si/CNFs in ethanol

Two kinds of multi-component suspensions were prepared: the one consisting of Si-OH and CNFs-COOH (7%) and another one consisting of Si-NH$_2$ and CNFs-COOH (7%). Unless mentioned otherwise, the concentrations of CNFs-COOH and modified-Si are 0.5 mg/mL and 0.2 mg/mL, respectively.

1) Zeta potential

As shown in Fig.6.21, Si-OH/CNFs-COOH has the relative high zeta potential (|zeta potential| > 25mV) over a wide pH range (8 – 11) in ethanol, and the maximum absolute value is about 36 mV at pH11. It’s noticed that the zeta potential profile of Si-OH/CNFs-COOH is highly similar to that of CNFs-COOH. Because of the low concentration of each component and poor interaction between –OH and –COOH groups, the ionization process of Si-OH and CNFs-COOH is relatively independent. Meanwhile, the charged Si-OH can be considered as a special free ion around CNFs to increase the electrostatic repulsion between CNFs, leading to a little improvement of stability in comparison with pure CNFs-COOH suspension.

Fig.6.21: Profiles of zeta potential values in different CNFs/Si suspension (ethanol)
In the Si-NH$_2$/CNFs-COOH suspension, except for free charged Si-NH$_2$ and CNFs-COOH, some Si particles can locate on the CNFs surface via the electrostatic attraction between –NH$_2$ and –COOH groups, leading to the decrease of surface charge density of CNFs and reducing the repulsive force between CNFs. Therefore, as shown in Fig.6.21, although the changing tendency of zeta potential profile is similar to the others, the global stability is decreased. The metastable state can be only obtained at pH 10 – 11, and the maximum absolute value is about 30 mV at pH11.

The functional group of Si can influence the zeta potential of multi-component aqueous suspensions in the same way, as shown in Fig.6.22. To be specific, a stable Si-OH/CNFs-COOH suspension can be obtained at pH 5 – 11, and the zeta potential can be up to -46 mV at pH 9. If pH >9, free –OH are too excessive and the electric double layers of charged particles become thinner, leading to the decrease of the zeta potential. In the Si-NH$_2$/CNFs-COOH suspension, a stable state can be obtained at pH 7 – 11, and the maximum absolute value is about 42 mV at pH11.

Fig.6.22: Profiles of zeta potential values in different CNFs/Si suspension (water)

Fig.6.23 shows the influence of the composite concentration on zeta potential in ethanol. For Si-OH/ CNFs-COOH suspensions, the concentration cannot change the I.E.P. value (2.2),
and has no influence on the zeta potential around I.E.P. At pH 1–1.5 and pH 3–10, the absolute value of zeta potential will increase a little as the increase of the concentration. But if the concentration is too high (1.8 mg/mL), under the strong acidic (pH 0.5–1) or strong basic (pH 10–11.5) conditions, the absolute value of zeta potential will decrease due to more collision of particles.

![Graph](image)

**Fig. 6.23: Profiles of zeta potential versus pH value in Si-OH/CNFs-COOH suspension with different concentration.**

For Si-NH₂/CNFs-COOH suspensions, the identical changing tendency can be also observed when the pH value is lower than I.E.P (3.5), as shown in Fig. 6.24. Under the strong alkali conditions (pH >9), too high concentration is harmful to the suspension stability.
Fig. 6.24: Profiles of zeta potential versus pH value in Si-NH$_2$/CNFs-COOH suspension with different concentration.

If the ratio of modified-Si to CNFs-COOH is changed, the zeta potential profile will be also changed, as shown in Fig. 6.25. It’s found that the absolute value of zeta potential increases with the ratio of Si-OH to CNFs-COOH at the same pH, but decreases with the ratio of Si-NH$_2$ to CNFs-COOH. Based on the interaction among different functional groups, in a given solvent, the increase of Si-OH can be equivalent to the increase of $-\text{COOH}$ groups on the CNFs surface, while the increase of Si-NH$_2$ is equivalent to the reduce of $-\text{COOH}$ groups. As mentioned in Part 3, more $-\text{COOH}$ groups means more surface charge in the suspension. Therefore, more Si-OH or less Si-NH$_2$ groups with a fixed CNFs concentration is beneficial to improve the suspension stability in a wide pH range (0.5 – 10).
Fig. 6.25: Profiles of zeta potential versus pH values in modified-Si/CNFs-COOH suspension with different ratio of Si to C.

2) Settling rate
Based on the zeta potential results, some pH values are chose for preparing metastable/stable multi-component suspensions with different concentrations in ethanol, as shown in Table 6.8.

Table 6.8 Zeta potential values for modified-Si/CNFs in different suspensions (ethanol)

<table>
<thead>
<tr>
<th>Particles</th>
<th>Concentration in ethanol (mg/mL)</th>
<th>pH</th>
<th>Zeta potential (mV)</th>
<th>State of stability</th>
</tr>
</thead>
<tbody>
<tr>
<td>Si-OH/CNFs-COOH</td>
<td>0.4/1</td>
<td>0.5</td>
<td>23</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>9</td>
<td>-32</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>10</td>
<td>-35</td>
<td></td>
</tr>
<tr>
<td>Si-NH₂/CNFs-COOH</td>
<td>0.4/1</td>
<td>0.5</td>
<td>21</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>9</td>
<td>-28</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>10</td>
<td>-32</td>
<td></td>
</tr>
</tbody>
</table>

Fig.6.26: Profiles of RSH value versus standing time for different suspensions in ethanol.

For Si-OH/CNFs-COOH composite in ethanol, as shown in Fig.6.26a, the suspensions at pH9 and pH10 exhibit good stability for a long time with the initial RSH of 8% and 6%, and the
corresponding $C_{rd}$ after 1h is 85% and 90% (Table 6.9). At pH0.5, the particle settlement is serious because of low zeta potential. Considering the relatively independence between Si-OH and CNFs-COOH in ethanol, each component settles with its own settling rate, leading to the separation of Si and carbon settlement zones like Fig.6.27, so the RSH value here makes no sense.

![photograph](image)

Fig.6.27: Photograph of Si-OH/CNFs-COOH suspension in ethanol at pH0.5 after 1h standing.

For Si-NH$_2$/CNFs-COOH system, as shown in Fig.6.26b, at pH0.5, pH9 and pH10, the initial RSH value is 23%, 12% and 7%, respectively, and it changes to 13%, 9% and 6% after 1h standing, indicating the sample at pH10 has an improved stability. These three samples’ $C_{rd}$ values are 55%, 75% and 85%, respectively.

Table 6.9: $C_{rd}$ values for different composite suspensions in ethanol.

<table>
<thead>
<tr>
<th>Standing time (h)</th>
<th>$C_{rd}$ (%)</th>
<th>Ethanol at pH0.5</th>
<th>Ethanol at pH9</th>
<th>Ethanol at pH10</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>Si-OH/CNFs-COOH</td>
<td>Si-NH$_2$/CNFs-COOH</td>
<td>Si-OH/CNFs-COOH</td>
<td>Si-NH$_2$/CNFs-COOH</td>
</tr>
<tr>
<td>0.25</td>
<td>-</td>
<td>80</td>
<td>90</td>
<td>85</td>
</tr>
<tr>
<td>0.5</td>
<td>-</td>
<td>70</td>
<td>85</td>
<td>80</td>
</tr>
<tr>
<td>1</td>
<td>-</td>
<td>55</td>
<td>85</td>
<td>75</td>
</tr>
</tbody>
</table>
Summarizing the above results, the suspensions at pH 9 – 10 are good for short-time multi-component EPD, or else the non-homogenous film is prepared.

3) Applied Voltage

Based on the analysis of multi-component suspension stability, Si-OH/CNFs suspensions at pH10 and Si-NH$_2$ /CNFs suspension at pH0.5 in ethanol were prepared respectively with a concentration of 0.7 mg/mL ( weight ratio of Si to CNFs: 2/5). It’s noticed that the latter system has the relatively high initial RSH and low zeta potential, leading to the rapid decrease of the concentration in the homogeneous zone in the first 2 hours once the suspension is prepared. Therefore, 2h standing time is necessary if using Si-NH$_2$ /CNFs acidic suspension for EPD procedure. EPD process was performed at 15 - 75 V/cm for 10min. After the deposition, the yield of each sample was measured, as shown in Fig.6.28.

![Fig 6.28: Profiles of the deposited mass versus applied voltage in modified-Si/CNFs suspensions.](image)

Fig 6.28 shows the applied voltage’s effect on the deposited layer. In the Si-OH/CNFs-COOH suspension at pH10, the deposited mass is higher than that in the CNFs-COOH suspension under the same electric field because of the similar stability and the simultaneous
deposition of Si-OH particles. It also increases with the applied voltage and the maximum value at 75 V/cm is about 1.22 mg/cm². However, excessive voltage is not good for the uniformity of the deposited film. Under the electric field of 45 V/cm, the final film has smooth surface without any visible pores or cracks (Fig.6.29a). If increasing the voltage to 75 V/cm, although more particles are deposited in the same time, they don’t have enough time to adjust their location on the substrate to form a dense film because of high deposition rate and turbulence effect [91], finally, a film with non-uniform distribution of Si-OH/CNFs is formed (Fig.6.29b). Therefore, the applied voltage during EPD must strike a balance between the deposited mass and film morphology. The proper voltage here should be around 45 V/cm.

![Fig.6.29: Photographs of Si-OH/CNFs deposition film after 10min EPD in ethanol at pH10 with different applied voltages. a) 45V/cm, b) 75V/cm.](image)

At pH0.5, the Si-NH₂/CNFs-COOH suspension (zeta potential: 21 mV) is less stable than the CNFs-COOH one (zeta potential: 28 mV) with the same concentration; therefore, the deposited mass under the same electric field becomes lower. If the voltage is high enough, the faster initial deposition rate can partly overcome the negative influence of the continuous settlement, leading to an improved deposited mass for a short-time EPD. The maximum value of 0.82 mg/mL is obtained at 75 V/cm. Similarly, the excessive voltage also causes non-uniform of distribution of particles. What’s worse, high applied voltage during EPD in the strong acidic suspension means more serious hydrolysis reaction and more bubbles near the conductive substrate. As a result, the adhesive force between the porous film and Cu foil is weak, and the
film is likely to fall off during moving, shaking or other after-treatment process, as shown in Fig. 6.30. After 10min EPD, two films are taken out of the suspension immediately, and the 10s fast-jitter test is applied. It’s found the one prepared under higher electric field (75 V/cm) is totally damaged, while another one keeps the integrity well. Therefore, for EPD of Si-NH₂/CNFs-COOH in the strong acidic condition, the applied voltage must be lower than 60 V/cm.

Fig. 6.30: Photograph of Si-NH₂/CNFs-COOH deposition films (a: 60V/cm, b: 75V/cm) after 10s fast-jitter test.

The profiles of the current changing with time at different voltages in the Si-OH /CNFs-COOH suspension (pH10) are shown in Fig. 6.31. The introduction of Si makes the deposited layer having lower conductivity, leading to lower current during EPD in comparison with pure CNFs deposition at the same electric field. At 30 V/cm or 60 V/cm, when the decrease trend of the current looks similar that in CNFs suspension (> 400s), meaning less SiNPs are deposited onto the composite surface. At 45 V/cm, the current is continuously decreasing during the whole EPD process, indicating more SiNPs are deposited. The possible reason for the continuous Si deposition is that the balance between Si settling rate with deposition rate can be obtained under such electric field.
Fig. 6.31: Profile of current versus time in Si-OH/CNFs-COOH suspension

Fig. 6.32: Profile of current versus time in Si-NH$_2$/CNFs-COOH suspension

Fig. 6.32 shows the current changing with time at different voltages in the Si-NH$_2$/CNFs-COOH suspension (pH0.5). Each profile’s changing tendency is highly similar to the one in the
CNFs suspension, which means the formation of the Si-NH$_2$ / CNFs layer also follow the three-stage growth mechanism. Because of the interaction between –NH$_2$ groups and –COOH groups, some SiNPs are locating along the surface of CNFs, leading to lower conductivity of the CNFs, and smaller current value at the same applied voltage in comparison with CNFs deposition.

Fig.6.33 shows the influence of time on the deposited mass in Si-OH/CNFs-COOH suspensions. The existence of Si-OH improves the stability of CNFs in the composite suspension, so the deposited mass of 0.94 mg/mL and 1.22 mg/mL after 10 and 15 min deposition are larger than those obtained in the CNFs suspension (0.75 mg/mL, 0.84 mg/mL). However, the introduction of Si-NH$_2$ makes the stability of the CNFs decreased a little, the corresponding deposited mass become lower in comparison with that in CNFs suspension with the same deposition time. The deposited mass after 10 min and 15 min deposition decreases from 0.58 mg/mL and 0.62 mg/mL to 0.52 mg/mL and 0.56 mg/mL, respectively.

Fig.6.33: Profiles of deposited mass versus time in different suspensions

6.6 Preparation of Si/CNFs composite film with honeycomb structure

The composite film consisting of Si-OH and CNFs with honeycomb structure can be prepared by homogeneous EPD with the help of lithium borate (Li$_2$B$_4$O$_7$) in ethanol at pH10.

1) Si film on Cu foil
As the control test, a Si-OH film was prepared firstly by EPD, as shown in Fig.6.34. The film can cover the whole Cu substrate but also has many cracks. From the broken surface of the film (the insert image), the aggregation of a large number of Si particles can be observed. Considering the poor conductivity of Si, such microstructure greatly inhibits the diffusion of Li$^+$ and makes the lithiation/delithiation process hard for the inner part.

Fig.6.35a shows the cycling performance of the Si-OH film. The first discharge capacity is about 1900 mAh/g at the current rate of 400 mA/g, much lower than the theoretical specific capacity (4200 mAh/g), indicating the formation of Li$_2$Si in the end. The first charge capacity is about 600 mAh/g and the initial CE is only 32%, indicating the seriously irreversible consumption of Li$^+$ due to the formation of SEI. After the first cycle, the discharge/charge capacity is decreased rapidly and very soon is lower than 200 mAh/g. It’s related to by the collapse of the film structure and the loss of the contact between Si and Cu due to the volume change effect during cycles. Fig.6.35b shows the voltage profiles of different cycles. During the first discharge process, the voltage platform from 1V to 0.5V is corresponding to the formation of SEI, and the following slant platform (0.5 - 0.1 V) should be attributed to the lithiation of Si. The first delithiation process starts with 0.6 V, higher than the literature data. After the first cycles, the platform of the SEI formation disappears and only very short lithiation/delithiation platforms can be observed, exhibiting the discharge capacity of 310, 190 and 177 mAh/g at the 2$^{nd}$, 40$^{th}$, and 100$^{th}$ cycle, respectively.
Fig.6.35: a) cycle performance of Si-OH film; b) galvanostatic discharge-charge curves for the Si/CNFs film.

2) Morphology of Si/CNFs film with honeycomb structure
A typical composite film is successfully prepared by 10 min EPD, as shown in Fig. 6.36. At the low magnification (Fig. 6.36a), the film has the intact net-structure consisting of the twisted CNFs and Si particles. No exposed Cu substrate can be observed. The insert image shows the film has good flexibility, good mechanical strength and good adhesion with the Cu. At the high magnification (Fig. 6.36b), it shows the non-uniform distribution of Si in the film. Si particles prefer gathering together in the interspace of the net structure to being along with CNFs, which is related to the repulsive force between Si and CNFs due to –OH groups at the Si surface and –COOH groups at the CNFs surface. Therefore, most CNFs still have the smooth surface after the deposition. Fig. 6.36c shows the film has an uneven surface with the thickness of 25 – 35 μm, and Fig. 6.36d confirms that Si distribution is still non-uniform in the vertical direction.

Fig. 6.36: a) low-magnification and b) high-magnification SEM images of the CNFs/Si film; c) lower-magnification and d) high-magnification SEM images of the cross section of the composite film.

TGA and the corresponding DTG curves (the derivative of the TGA), as shown in Fig. 6.37, can provide more accurate content of each component of the film. It can be divided into four mass loss sections. The first one below~150°C is due to the release of the surface moisture.
Then, the degradation of carboxyl group happens, which reaches its maximum loss rate at around 200°C, and completes at about 400°C. The third section in the range of 400°C to 750°C is attributed to the pyrolysis of CNFs. Different sizes and defects distribution of CNFs lead to different loss rates. The sample retains about 22 wt% after reaching 750°C. Over this temperature, the increase of the mass can be observed, which is might be caused by the formation of the thin layer of SiOₓ. Ignoring the minor formation of SiOₓ during the test below 750°C, the Si content in the composite can thus be estimated as 22 wt%. Based on the initial specific capacities of Si-OH film and CNFs-COOH film as discussed before, the maximum theoretical specific capacity of the composite film is about 630 mAh/g.

Fig. 6.37: TGA profile of Si/CNFs composite

In order to further realize the microstructure, the morphology evolution of the film has been studied, as shown in Fig. 6.38 and 6.39. A deposit layer with the mesh pattern is formed in a very short time (Fig. 6.38a), which exhibits discontinuous pores ranging from 20 ~ 35 μm. The magnified SEM image (Fig. 6.39a and b) shows CNFs are interweaved into a dense net and SiNPs are mixed with them simultaneously. Few SiNPs or CNFs are found in the pores. As time
advance, the number of mesh decreases (Fig. 6.38b) and the layer become thicker with a little more Si (Fig. 6.39c and d). When the deposited time is extended to 10 min (Fig. 6.38c), large pores nearly disappear while massive accumulation of the composite in some regions happens. Over 10 min, the growth of the deposit layer becomes slower, as shown in Fig. 6.38d. Considering the uniformity of the microstructure, 5~10 min EPD is a better choice.

Fig. 6.38: SEM images of Si/CNFs composite film with different deposition time. a) 1 min, b) 3 min, c) 10 min, d) 15 min.

It’s believed that the formation of such microstructure is with relation to the electrolytes. If only LiOH used, the deposit with the irregular pattern instead of the mesh (Fig. 6.40a) happens at the beginning, which includes a large number of SiNPs attaching to the loose CNFs. After 10 min, as shown in Fig. 6.40b, the porous film is formed with the similar surface micro-morphology (Fig. 6.40c) to the previous one. However, its cross-section SEM image (Fig. 6.40d) shows different characteristics. The inhomogeneous distribution of SiNPs along a line perpendicular to the copper foil can be observed. Especially at the bottom of the film, the SiNPs with few CNFs are severely agglomerated, indicating the initial mobility rate of Si is higher than that of CNFs. The introduction of a small amount of Li$_2$B$_4$O$_7$, an electrolyte salt, may improve the quality of
the film from two aspects with little effect on pH value of the suspension. One side, $\text{B}_4\text{O}_7^{2-}$ has faster mobility rate than negative charged SiNPs because of higher electric charge density, which leads to “shield” Si and make Si “waiting for” CNFs in the early stage of deposition. On the other side, the existence of $\text{B}_4\text{O}_7^{2-}$ makes the particle’s diffusion layer thicker, resulting in the increase of the repulsive force among the deposited tangled CNFs and upcoming deposited ones and finally forming the mesh pattern.

Fig. 6.39: SEM images of the Si/CNFs composite film after (a, b) 1min and (c, d) 3min EPD
Fig. 6.40: SEM images of the Si/CNFs composite film without the assistance of lithium borate after a) 1 min, b, c) 10 min EPD, d) the cross-section image of the film after 10 min EPD.

Generally, salt additives influence the deposited layer via two ways. Firstly, different ions’ size can change the thickness of the electric double layer of the charged particles, leading to different zeta potential values. As a result, the suspension stability/the settling rate of particles is changed, which can greatly influence the morphology and uniformity of the deposited layer. Secondly, as the increase of the free ions’ concentration, the mobility rate of particles in the suspension will be changed greatly. For the multi-component system, it can influence the content of each component in the deposited film, as shown in Fig. 6.42. If LiClO$_4$ is added, the composite film becomes non-uniform (Fig. 6.42a, b). The cracks and bumps on the surface can be observed at the same time. If Li$_2$CO$_3$ is used, the composite film looks similar as that prepared with the additive of Li$_2$B$_4$O$_7$. The morphology difference may be caused by Li$^+$ concentration. Although both Li$_2$CO$_3$ and LiClO$_4$ have larger negative ions than OH$^-$, Li$_2$CO$_3$ can provide more Li$^+$ in comparison with LiClO$_4$, leading to easier neutralization of negative-charged Si and CNFs when deposition happens and better distribution of CNFs net.
Fig. 6.41: SEM images of Si-OH/CNFs composite at a) high-magnification and b) low magnification with LiClO₃ additives; SEM images of Si/CNFs composite at c) high-magnification and d) low-magnification with Li₂CO₃ additives.

Fig. 6.42: SEM and EDX images of Si-OH/CNFs-COOH composite films with the applied voltages of a, d) 30 V/cm, b, e) 45 V/cm and c, f) 60 V/cm.

For EPD of Si-OH/CNFs-COOH in ethanol, as discussed before, if considering the integrity and uniformity of the final film, pH10 is the best choice for a stable multi-component suspension, and the proper applied voltage is around 45 V/cm. Actually, the film’s component
and microstructure can be influenced a little by applied voltage (30 ~ 60 V) if pH value is fixed to 10, as shown in Fig.6.42. Firstly, applied voltage cannot change the basic structure of the composite. SiNPs still are distributed randomly in the continuous CNFs skeleton. As the increase of the voltage from 30 V/cm (Fig.6.42a) to 45 V/cm (Fig.6.42b), the microstructure keeps unchanged and the Si content increases a little. At 60 V/cm, higher voltage leads to faster Si migrating rate and weaker space effect of CNFs on Si distribution during deposition, therefore, the aggregation of SiNPs becomes more serious (Fig.6.42c).

In order to adjust the morphology of the film, some kinds of surfactants are introduced, as shown in Fig.6.43 and 6.44. After adding TX-100, the film is still intact without any cracks. CNFs net are changed little, while the aggregated SiNPs among CNFs become loose due to the space effect of TX-100. If using ionic surfactant, the film morphology is changed a lot. With SDS additive (anionic surfactant, Fig.6.44a and b), more CNFs are intertwisting with each other due to the decrease of the size of EDL, leading to the formation of broken conductive net. If adding quaternary ammonium compound (cationic surfactant, Fig.6.44c and d) into the suspension, more Si particles are deposited at the bottom of film due to the reduced surface charges.

![Fig.6.43 SEM images of a) CNFs film, b, c, d) Si/CNFs films at different magnification with TX-100 additive.](image-url)
Fig. 6.4 SEM images of Si/CNFs composite a, b) with the additive of SDS and c, d) with the additive of quaternary ammonium compound at different magnifications;

3) Electrochemical properties

The voltage profile of the composite film at the current rate of 400 mA/g is shown in Fig.6.45. The film has the 1st discharge capacity of 1070 mAh/g, much larger than the theoretical value (630 mAh/g). The excess part should be related to the decomposition of the electrolyte. The 1st charge capacity is 580 mAh/g and the ICE is only 54.2%. There is a main platform starting with 0.45 V on the first discharge curve possibly due to the formation of SEI and Li$_x$Si alloying. In the second cycle, the discharge and charge capacity is about 570 mAh/g and 490 mAh/g, and the CE is 86%. The sloped platform starting with 1.1 V indicates the continuous growth of the SEI layer. However, all the charge profiles have much higher delithiation platform than the literature data, which is consistent with the results of the CV profiles (Fig.6.45b). In the first cycle, a cathodic peak around 0.45 V and an anodic peak around 1.6 V can be observed, and these two peaks become much wider during the following cycles. Meanwhile, a new anodic peak around 0.6 V appears which should be attributed to the extraction of Li$^+$ from the Li$_x$Si/LiC$_y$ alloy. The impurity in the composite film is the main reason for the high delithiation platform and broad peaks. In the alkali suspension, negative-charged Si-OH particles move toward to the positive electrode (Cu foil) during the deposition process. At the
same time, the corrosion of Cu cannot be avoided. Some Cu atoms are oxidized to Cu$_2$O and the mixture of CuO and Cu(OH)$_2$, finally forming a passivation layer between Cu foil and the composite layer. The inert layer makes the transport of Li$^+$ harder, which can inhibit the normal growth of the SEI layer and lithiation/delithiation process.

Fig.6.45: a) Galvanostatic discharge-charge curves for the CNFs/Si composite film; b) cyclic voltammetry profiles of the Si/CNFs composite film.
Removing the inert layer by using the proper acidic solution, the “real” voltage profiles and CV profiles of the composite film can be obtained, as shown in Fig 6.46.

Fig. 6.46: a) Galvanostatic discharge-charge curves for the CNFs/Si composite film after washing; b) cyclic voltammetry profiles of the Si/CNFs composite film after washing.

Compared with the film without washing, the 1st discharge and charge capacities are decreased a little to 1040 mAh/g and 535 mAh/g, while the ICE almost keeps unchanged. A
main flat region at 1.1 V on the 1st discharge should be assigned to the formation of SEI layer, and drops gradually as more Li⁺ alloying with Si/C. On the following discharge curves, the high voltage platform disappears and only one region at 0.2 – 0.3 V corresponding to the conversion of amorphous Si and C to LiₓSi/LiCᵧ can be observed. Similarly, there is only one platform at 0.2 – 0.5 V corresponding to the extraction of Li⁺ from LiₓSi/LiCᵧ on each charge curve, which indicates high stability of the inner battery. From the CV curve, the cathodic peak around 1.1 V during the 1st discharge is assigned to the formation of a SEI layer, which disappears in the following cycles. It means the SEI layer is completely formed in the 1st cycle and keeps stable. Another cathodic peak around 0.25 V is assigned to the formation of the amorphous LiₓSi and LiCᵧ. Two anodic peaks at 0.35 V and 0.5 V can be found on each charge curve, which are corresponding to the transformation of LiₓSi/LiCᵧ to amorphous Si and CNFs. It’s noticed that the intensity of the current increases with the cycle numbers, which may be related to the gradual activation of Si particles during the test.

As shown in Fig.6.47a, after the first several cycles, the discharge/charge capacity of the composite film remains stable and the CE value almost keeps 100%. A reversible discharge/charge capacity of 500 mAh/g after 60 cycles can be obtained, much higher than that of Si film or CNFs film. One reason for the improvement of the cyclability is CNFs net-structure can effectively improve the film conductivity and provide enough space to accommodate Si volume change during lithiation/delithiation to maintain the integrity of the structure. However, after 60 cycles, the capacity drops slowly as the increase of the cycle number, and the discharge/charge capacity is only 360 mAh/g in the 100th cycle. It indicates the link between Si and CNFs is not strong enough. Although the integral structure can be maintained, the aggregated Si particles may lose the contact with CNFs, leading to the damage of the conductive framework and the loss of the active materials.

The rate performance of the composite film is shown in Fig.6.47b. With the increasing of the current rate from 400 to 800, 1600 and 3200 mA/g, the specific capacity decreases from 460 to 280, 260 and 250 mAh/g, respectively. When the current rate returns to 400 mA/g, the capacity can be returned to 430 mAh/g after 90 cycles. Generally, at a high current rate, the time for Li⁺/electron transport in the active material is very limited and the conductivity is the key on the lithiation/delithiation process. Therefore, poor link between CNFs and Si in the composite film leads to its bad rate performance.
Fig. 6.47: a) cycling performance and b) rating performance of the Si/CNFs film after washing.

To further understand the effect of cycling on the microstructure of the composite film, a half cell in the charge state after 60 cycles was disassembled. The SEM image (Fig. 6.48a) clearly shows that the film is well retained without any obvious crack, and membranoid substances in some areas are also observed, which might belong to the SEI layer. Si particles are found to be wrapped by such membranoid substances to stay close to CNFs at high magnification (Fig. 6.48b). The cross-section image (Fig. 6.48c) indicates the film’s thickness changes little, still
around 30 μm, which demonstrates that the meshed porous structure can effectively relieve the stress from volume change of Si particles during lithiation and delithiation process, and the magnified image (Fig.6.48d) shows no aggregated Si particles are exposed at the CNFs surface. All the images verify that this composite film has great structure stability and keeps good electric contacting between CNFs-COOH and Si-OH in the first 60 cycles.

Fig.6.48: SEM images of CNFs/Si composite after 60 cycles. a, b) top view, c, d) cross section.

Fig.6.49 shows the influence of applied voltage on film’s cycling performance. At low applied voltage (30 V/cm), the deposited film has less Si content (Fig.6.42d), therefore, the 1st discharge capacity is decreased from 1040 mAh/g to 914 mAh/g. Meanwhile, less Si content means better conductivity of the film, relieved volume effect and more stable SEI layer, leading to higher 1st charge capacity (635 mAh/g) and higher ICE (69%). In the following cycles, the Coulombic efficiency rapidly increases to 100% and keeps unchanged. After 100 cycles, the discharge capacity is 336 mAh/g, which is still higher than that of pure CNFs (280 mAh/g). At high applied voltage (60 V/cm), although the deposited film has higher Si content (Fig.6.42f), serious aggregation of SiNPs affects the film cycling performance in a negative way. The 1st cycle discharge and charge capacity are 1200 mAh/g and 711 mAh/g, respectively, and the ICE is very low (57%). Starting with the 2nd cycle, the discharge and charge capacities are decreased
to around 280 mAh/g and change little in the following 100 cycles, meaning the capacity of the composite film mainly comes from CNFs rather than SiNPs. Therefore, for Si-OH/CNFs-COOH system, 45V/cm is the best applied voltage value in ethanol at pH10 to achieve both high uniformity of the film and improved electrochemical performance.

Fig.6.49: Cycling performance of the composite film prepared with different applied voltages. Fig6.50 shows the SEM images of the composite films with different initial ratios of Si to CNFs. Each sample has the similar net structure consisting of CNFs, indicating the amount of Si has little influence on the deposition of CNFs. When the initial ratio is low (1/5), it’s hard to find the aggregated Si at the surface. If the initial ratio is high (4/5), the aggregation of Si among CNFs becomes more serious.
Fig. 6.50: SEM images of Si/CNFs films with different initial ratios of Si to CNFs. a, b) 1:5; c, d) 4:5.

Fig. 6.51 shows the influence of the amount of Si on the cycling performance. If the initial ratio is 1:5, the 1\textsuperscript{st} discharge and charge capacity is 450 and 240 mAh/g. In the following 10 cycles, the capacity increases with the cycle number, which is possibly caused by activation of Si locating at the bottom of the film. Then, the capacity remains stable and 365 mAh/g can be obtained after 100 cycles. If the initial ratio is 4:5, the 1\textsuperscript{st} discharge and charge capacity can be up to 1335 and 681 mAh/g and the capacity of 600 – 620 mAh/g can be maintained in the first 60 cycles. Like the sample with the ratio of 2:5, this composite film also has a decreased capacity after 60 cycles because of the broken conductive net. In the 100\textsuperscript{th} cycle, the capacity is about 433 mAh/g. As shown in Fig. 6.51b, these three samples have the similar ICE values (53%, 54.2% and 51%). After the first several cycles (generally <10), the sample with the ratio of 1:5 or 2:5 has very high CE (>98%), which almost keeps unchanged during the test. However, the sample with the ratio of 4:5 shows unstable CE curve. It means the SEI layer would be broken and regrow during cycles. Therefore, higher Si content in the film brings higher specific capacity.
after 100 cycles, but more electrolyte and Li atoms are irreversibly consumed, leading to unstable electrochemical properties.

Fig. 6.51: a) cycling performance of Si/CNFs films with different initial ratios of Si to CNFs; b) profiles of Coulombic efficiency of different Si/CNFs films.

Fig. 6.52 shows the influence of salt additives on cycling performance. Although a uniform Si/CNFs composite film (Fig.6.39c) can be prepared with the help of Li$_2$CO$_3$, the capacity is very low. The 1$^{\text{st}}$ discharge and charge capacity is only about 400 and 280 mAh/g.
After 100 cycles, the capacity is increased to 320 mAh/g, which is still too low to be used. The inactivity of Li₂CO₃ to Li⁺ transfer should be the main reason for such bad cycling performance.

Fig. 6.52: Cycle performance of Si/CNFs composite films with different salt additives.

Fig. 6.53 shows the influence of surfactant on electrochemical properties of composite films. With the help of TX-100, Si/CNFs film exhibits better cycle life with the capacity of 510 mAh/g after 300 cycles. Except the first cycle, the Coulombic efficiency can be kept 100% during the entire process. However, if using ionic surfactant, as shown in Fig. 6.52b, the electrochemical properties of the composite films become worse, which are mainly caused by the non-uniform microstructure, as shown in Fig. 6.44.
Fig. 6.53: Profiles of cycle performance of Si/CNFs film a) with TX-100 additive, b) with ionic additives.

6.7 Preparation of Si/CNFs with necklace structure

1) Morphology

Fig. 6.54a shows the optical photo of the electrophoretically deposited film on the Cu foil, which presents good integrity and flexibility. The SEM image at a high magnification of the
surface of the film is shown in Fig.6.54b. Most Si clusters with an approximate size range from 200 nm to 1 μm are regularly distributed along the CNFs, which looks like “pearls” on a necklace. The thickness of the film is about 20 μm (inset of Fig.1b).

Fig.6.54 a) photograph of Si/CNFs film in ethanol at pH0.5, b) SEM image of Si/CNFs film in ethanol at pH0.5. The insert of b is the cross-section SEM.

The formation of such structure can be mainly attributed to the electrostatic interaction among SiNPs and CNFs during the co-deposition. SiNPs and CNFs are functionalized by amino groups (Si-NH$_2$) and carboxylic groups (CNFs-COOH) via surface pretreatment, respectively. Si-NH$_2$ has the positive-charged surface owing to ionization in the approximately neutral environment; while CNFs-COOH shows the negative charge. However, in the strong acidic suspension, both Si-NH$_2$ and CNFs-COOH have positive double electric layers (H$^+$ adsorption, Fig.6.55a), which means all the charged particles will move towards the negative electrode as applying DC electric field (Fig.6.55b: stage 1). According to previous research, the double electric layers are asymmetric in the moving direction with thinner ahead and wider behind. When these particles are close to the electrode, local concentration is increased, which induces the distortion of the double layers and the coagulation process: the thin part of one double layer blend in with another one’s extended tail. For the functionalized SiNPs and CNFs, the coagulation is directional, not random. SiNPs are inclined to choose CNFs as “the partner” rather than other SiNPs because of electrostatic attraction between –NH$_2$ and –COOH (Fig.6.55b: stage 2), so are CNFs. When the particles contact the substrate or formerly deposited layer, the absorbed H$^+$ are depleted (obtaining electrons from the negative) and the double layers are gone. Most of SiNPs still keep staying on the surface of CNFs and finally the necklaced-like structure is formed (Fig.6.55b: stage 3). In contrast, the composite film with pure SiNPs and CNFs is
prepared under the same conditions, which clearly shows “clean” CNFs surface and seriously aggregated SiNPs (Fig.6.56).

![Diagram of deposition process](image)

**Fig.6.55:** Scheme of the deposition process in Si/CNFs suspension.

![SEM images](image)

**Fig.6.56:** SEM images of Si/CNFs composite film without Si surface treatment. a) low magnification, b) high magnification.

Importantly, the improvement of SiNPs distribution is not confined to the film surface. Fig. 6.57 shows the SEM images of the deposited layers with different EPD time. After 1 min (Fig.6.57a), a film on the Cu foil consisting of “clean” CNFs and necklace-like Si/CNFs composite is initially formed; while little SiNPs aggregate in the interspace or on the “naked” substrate. The coexistence phenomenon of multi morphologies of CNFs can be attributed to two reasons. 1) CNFs have higher initial concentration than SiNPs; 2) CNFs still have faster mobility rate than SiNPs under the similar condition due to the instability of Si in ethanol. The electrostatic interaction effect doesn’t work well during the migration process because both Si-
NH₂ and CNFs-COOH have a positive double electric layer in the strong acidic suspension, meaning SiNPs cannot be attached to CNFs beforehand. After 2 min (Fig. 6.57b), the film continues growing and has already covered 100% substrate. SiNPs are still regularly distributed along CNFs. Moreover, by contrasting Fig6.57a, 6.57b and Fig.6.54b, the proportion of the necklace-like structure is getting higher and higher with the time increasing, which indicates a gradual increase in Si content in the vertical direction to the film.

Fig.6.57: SEM images of a) Si/CNFs composite after 1 min EPD, b) Si/CNFs composite after 2 min EPD.

Fig.6.58: SEM images of a) Si/CNFs composite after 10 min EPD. Weight ratio of Si to CNFs: a) 1:5, b) 4:5.

The initial ratio of Si to CNFs has also influenced the microstructure of Si/CNFs film, as shown in Fig.6.58. When the ratio is low (Fig.6.58a), all the SiNPs are distributed along CNFs. No particles among CNFs’ space can be observed. As increasing the initial ratio of Si to CNFs to 0.8, bulk SiNPs anchored with CNFs are growing excessively, and part of them falls off, indicating the contact between Si and CNFs is weak.
If the magnetic stirring is going on slowly during EPD to make the mixture of Si and CNFs better as they are moving towards the electrode, a dense composite film can be also prepared, as shown in Fig.6.59a. Moreover, the distribution of Si is improved. No serious aggregation of SiNPs is observed even on the surface of CNFs.

![Fig.6.59: SEM images of the Si/CNFs composite film under the magnetic stirring conditions. a) low magnification; b) high magnification.](image1)

If depositing CNFs and Si-NH$_2$ on the Cu foil by step-by-step EPD, the necklace-like structure cannot be maintained, as shown in Fig.6.60. After 5 min EPD in CNFs-COOH suspension at pH0.5, a continuous conductive net is formed (Fig.6.60a). In the following deposition process of Si-NH$_2$, CNFs surface is covered by bulk SiNPs, indicating the interaction between –NH$_2$ and –COOH doesn’t work. Therefore, the pre-mixing of SiNPs and CNFs is necessary to obtain the necklace-structural film.

2) Electrochemical properties
Fig. 6.61: a) Galvanostatic discharge-charge curves for the necklaced-like CNFs/Si composite film; b) cycling performance of the Si/CNFs composite film.

The voltage profile of the composite film at the current rate of 400 mA/g is shown in Fig. 6.61. The film has the 1st discharge capacity of 1192 mAh/g and the 1st charge capacity is 1070 mAh/g and the ICE is 84.2%. There is a main platform starting with 0.45 V on the first discharge curve possibly due to the formation of SEI and \( \text{Li}_x\text{Si} \) alloying. In the second cycle, the
discharge and charge capacity is about 1027 mAh/g and 1004 mAh/g, and the CE is 97.8%. The sloped platform starting with 1.5 V indicates the continuous growth of the SEI layer and the activation of Cu$_2$O impurities. As shown in Fig.6.61b, this film exhibits very good cycling performance at 400 mA/g. After 100 cycles, the discharge and charge capacity can be up to 1020 mAh/g and 1000 mAh/g. The coulombic efficiency stays 99% during the whole test except the first cycle. The excellent electrochemical performance should be attributed to the specific structure. On the one hand, the contact between Si and CNFs via van der Waals force is beneficial to Li$^+$ and electrons transfer and suppressing the volume effect during cycles. On another hand, this structure means sufficient contact between Si and electrolyte, leading to the stable SEI formation during the first several cycles. Besides, little free SiNPs in the CNFs net lead to small decrease of the cycle capacity.

Fig.6.62: Cyclic voltammetry profiles of the necklaced-like Si/CNFs composite film

Fig.6.62 shows the CV profiles in the first two cycles of the composite film. The cathodic peak around 0.7 V during the 1$^{st}$ discharge is assigned to the formation of a SEI layer, which disappears in the 2$^{nd}$ cycle. It means most SEI layer is formed in the 1$^{st}$ cycle. Two anodic peaks at 0.32 V and 0.52 V in the 1$^{st}$ and 2$^{nd}$ charge curves are corresponding to the transformation of Li$_x$Si/LiC$_y$ to amorphous Si and CNFs.
The rate performance of the film is shown in Fig.6.63.

Fig.6.63: Rating performance of the necklaced-like Si/CNFs film.

With the increasing of the current rate from 400 to 800, 1600 and 3200 mA/g, the specific capacity decreases from 900 to 750, 580 and 550 mAh/g, respectively. It’s noticed that even the “worst” capacity value (at 3200 mA/g) is higher than most commercial anode materials’ capacities. When the current rate returns to 400 mA/g, the capacity can be returned to 774 mAh/g after 90 cycles. Therefore, the interaction between Si and CNFs cannot only promote the Li$^+$/electron transport in the active materials, but also maintain the basic framework very well after large current charging/discharging.

The SEM image of the morphology after 100 cycles is shown in Fig.6.64. It clearly shows that the necklace structure is well maintained. Si particles wrapped by membranoid substances (unwashed SEI layer) are still distributed along CNFs.
If increasing the initial Si ratio of CNFs from 2/5 to 4/5, the cycle performance of the film is shown in Fig. 6.65.

![Cycle performance of necklaced-like Si/CNFs film with high Si weight ratio.](image)

The first discharge and charge capacity of the film are 1180 mAh/g and 800 mAh/g. The ICE is about 68%. Then, both discharge and charge capacities keep going down. After 100 cycles, the discharge capacity is only 460 mAh/g. The reason for capacity decrease can be found in Fig. 6.58b. Too many SiNPs locates the same place on the CNFs surface, but only inner SiNPs
have the interaction with CNFs and the outer SiNPs would fall off during cycles, leading to the continuous decrease of the capacity.

Fig.6.66 shows the influence of magnetic stir on the film’s cycle life.

![Graph showing cycle performance of necklaced-like Si/CNFs film under stirring condition.](image)

Fig.6.66: cycle performance of necklaced-like Si/CNFs film under stirring condition.

In the first cycle, the discharge and charge capacity are 791 and 631 mAh/g, respectively, and the ICE is about 80%. The coulombic efficiency increases to 99% after 2 cycles and keep unchanged in the following 200 cycles. After 200 cycles, the discharge capacity can be up to 663 mAh/g, indicating very good cycle performance for this film. But the uneven cycle curve means the interaction between Si and CNFs is weaker under the stirring condition. SiNPs attached with CNFs are easily peeled off during cycles because of their volume effect. However, there are large contact area between Si and CNFs with the help of magnetic stirring, it’s easy for Si to re-link with CNFs via the interaction between −NH₂ and −COOH groups.

### 6.8 Summary

In this chapter, the stability of modified-Si/CNFs suspension and the corresponding deposition dynamics were investigated. Two kinds of Si/CNFs composite films with improved electrochemical properties were prepared by multi-component EPD. The results show:
1) EPD of modified-Si

Two kinds of functional groups, -OH and -NH$_2$, are introduced onto Si surface, respectively. The stability of Si-OH suspension in ethanol is improved. At pH10, Si-OH suspensions with the concentration of 0.2 – 0.8 mg/mL are stable in a short time (<1h). However, the stability of Si-NH$_2$ suspension is just improved a little. The deposition rates of both Si-OH and Si-NH$_2$ are influenced by voltage and time. The maximum deposition mass for Si-OH suspension at pH10 (0.24 mg/cm$^2$) can be obtained at 60 V/cm, while that for Si-NH$_2$ suspension at pH0.5 (0.14 mg/cm$^2$) can be obtained at 45 V/cm. During the deposition process, the Si film growth can be divided into three parts, and most particles are deposited in the second stage.

2) EPD of modified-Si/CNFs-COOH

If the initial concentration of modified-Si is low (0.2 – 0.4 mg/mL), the introduction of Si-OH can improve the stability of CNFs-COOH suspension in ethanol at pH 9~10, while adding SiNH$_2$ can decrease the stability of CNFs-COOH suspension. The suitable pH range for stable modified-Si/CNFs suspensions in ethanol is 9 – 10. Besides, Si-NH$_2$/CNFs suspension is metastable at pH 0.5. In the Si-OH/CNFs-COOH suspension at pH10, the deposited mass increases with applied voltage and the maximum value is about 1.22 mg/cm$^2$ at 75 V/cm. In the Si-NH$_2$/CNFs-COOH suspension at pH 0.5, the maximum deposited mass is about 0.82 mg/mL at 75 V/cm. However, high applied voltage damages the uniformity and integrity of composite films, so proper applied voltages for EPD should be lower than 60 V/cm. The deposited mass also increases with the deposition time. For EPD of Si-OH/CNFs-COOH suspension at pH10, the deposited mass of 1.22 mg/cm$^2$ can be obtained by increasing the time from 10 min to 15 min. Because the suspension of Si-NH$_2$/CNFs-COOH is metastable at pH0.5, prolonging time cannot increase the deposited mass too much (the maximum value is only 0.62 mg/cm$^2$).

3) Preparation of Si/CNFs film with honeycomb structure and the study of electrochemical properties

A composite film consisting of Si-OH and CNFs-COOH with honeycomb structure can be prepared by homogenous EPD in ethanol at pH10. The film has the intact net structure and Si particles are distributed in it randomly. The film thickness is about 25 – 35 μm. The formation of this structure is attributed to adding Li$_2$B$_4$O$_7$ as electrolyte additive. The morphology and structure of the film is greatly influenced by applied voltage, deposition time, salts and surfactant. The film exhibits improved electrochemical properties. After 60 cycles, the capacity can be up to
500 mAh/g. The Coulombic efficiency almost keeps 100% except the 1st cycle. With the help of TX-100, the cycle performance is improved further. The capacity can be up to 510 mAh/g at 400 mA/g after 300 cycles.

4) Preparation of Si/CNFs film with necklace structure and the study of electrochemical properties

A composite film consisting of Si-NH$_2$ and CNFs-COOH with necklace structure can be prepared by homogenous EPD in ethanol at pH0.5. All the Si particles are distributed along with CNFs surface. The film thickness is about 15 μm. The formation of this structure is attributed to the interaction between –NH$_2$ and –COOH groups. The film exhibits high capacity of 1020 mAh/g at 400 mA/g after 100 cycles. The rate performance is also good. The capacity can be up to 550 mAh/g at 3200 mA/g. With the help of magnetic stirring, less SiNPs are deposited but the distribution of Si along CNFs becomes more uniform, leading to a deceased capacity but longer cycle life. After 200 cycles, the capacity of the composite film is about 663 mAh/g.
Chapter 7
CONCLUSIONS

In this dissertation, different (meta)stable suspensions of Si/CNFs were prepared in ethanol by choosing proper pH value range and initial concentrations. A stable suspension is the most important precondition for homogeneous EPD of Si/CNFs system. Then, the uniform and integrated Si/CNFs composite films were prepared by using EPD only. The influence of applied voltage, deposition time, additives and other parameters on the film microstructure and the corresponding electrochemical properties are studied. There are at least three kinds of composite films that exhibit improved electrochemical properties. The results are listed as follow.

1) Sing-component EPD for Si and CNFs are studied, respectively. It’s noticed that surface modification is necessary to improve the stability of single-component suspension in ethanol. After introducing -COOH onto CNFs surface, CNFs suspension can keep stable at pH 9 - 11 and pH 0.5 with the concentration of 0.5 - 2 mg/mL. Without surface modification, there is no stable suspension for SiNPs in ethanol. After introducing –OH groups on Si surface, Si suspension with the concentration of 0.2 - 0.8 mg/mL becomes more stable at pH 10. It’s still hard to prepare stable Si-NH₂ suspension, but metastable suspension can be obtained at pH 0.5.

2) A stable CNFs suspension is the fundamental for preparing (meta)stable Si/CNFs suspensions in ethanol no matter what kind of Si is used. Because the initial concentration of Si is relatively low and the particle size is small, SiNPs have little influence on CNFs stability. For Si/CNFs-COOH, Si-OH/CNFs-COOH and SiNH₂/CNFs-COOH suspensions, the best pH values for short-time EPD are 10, 10 and 0.5, respectively. The deposited mass of the composite film increases with the applied voltage from 30 V/cm to 60 V/cm. If the voltage is over 60 V/cm, the uniformity and integrity of the deposition film is damaged. The deposited mass also increases with the deposition time, but the increasing trend slows down. Therefore, the optimal deposition time for film growth is about 10 ~ 15 min.

3) Using different SiNPs in the composite suspension, three kinds of films with different microstructure were prepared by EPD.

Firstly, under the simplest conditions (no Si surface treatment or any other additives), a Si/CNFs-COOH composite film is prepared in ethanol at pH10. The microstructure of the film
looks like a simply-mixing type discussed in Chapter 2.3.2. CNFs fabricate a continuous conductive net on Cu foil, and SiNPs are randomly distributed among the net spaces. There is no strong interaction between SiNPs and CNFs. The deposited mass is about 0.83 mg/cm$^2$. The film exhibits good cycle performance with the capacity of 610 mAh/g after 100 cycles but relatively low Coulombic efficiency (90%).

To increase Coulombic efficiency, Si distribution in the composite film must be improved to make SEI layer stable during cycles; therefore, the second sample with honeycomb structure was prepared in ethanol at pH10 with the help of Si surface modification and additives. The composite film consists of Si-OH and CNFs-COOH with the deposited mass of 0.9 mg/cm$^2$. The repulsive force between SiNPs due to –OH groups at the surface makes SiNPs dispersion better. The introduction of Li$_2$B$_4$O$_7$ makes EDL of CNFs thinner, leading to tight intertwist between CNFs. As a result, the film has the capacity of 500 mAh/g after 60 cycles with the Coulombic efficiency of nearly 100% except the 1st cycle. If adding TX-100 as the particle dispersant, no serious aggregation of SiNPs can be observed, and the corresponding film has the capacity of 510 mAh/g at 400 mA/g after 300 cycles.

Although the film with honeycomb structure exhibits high Coulombic efficiency and long cycle life, the capacity is relatively low. It’s necessary to make more SiNPs staying Li-active during cycles. An effective way is strengthening the interaction between CNFs and SiNPs on basis of well-distribution of SiNPs along CNFs. With the help of the electrostatic attraction between -NH$_2$ groups on the Si surface and -COOH groups on the CNFs surface, a composite film with necklace structure is prepared by EPD in ethanol at pH0.5. The acidic suspension is not stable enough; therefore, 2h standing time for the suspension is needed before EPD. In this film, SiNPs are regularly distributed along CNFs, which looks like “pearls” on a necklace. The deposited mass is about 0.5 mg/cm$^2$. The film has the capacity of 1020 mAh/g at 400 mA/g after 100 cycles. By introducing magnetic stirring during EPD, the composite film has less deposited SiNPs with better uniform distribution, which exhibits better cycle life with the capacity of 663 mAh/g after 200 cycles.

In the future, the experiment can be improved in at least two ways.

1) Strengthening the interaction between SiNPs and CNFs in the alkaline suspension. A film prepared in the alkaline suspension (at pH10) often has higher deposited mass than that in the acidic suspension, but most SiNPs are locating in the interspaces among CNFs rather
than being along with CNFs surface. Therefore, the interaction between Si and CNFs is weak, leading to short cycle life if Si content is high. There are two possible ways to solve this problem. One is introducing proper ionic surfactant into the suspension, which can tightly wrap SiNPs and CNFs at the same time or serve as an active bridge connecting SiNPs with CNFs via specific functional groups. Another one is introducing pyrolytic carbon coating process after EPD. With the help of the pyrolysis of sucrose, chitosan or conductive polymer under protective environment (Ar, H$_2$, et al), the composite film can be covered with a thin and dense carbon layer, which help maintain the stability of the entire structure.

2) Improving the deposited mass after acidic EPD. The film prepared in the acidic suspension (at pH0.5) has both high capacity and long cycle life, but the deposited mass is relatively low, which cannot be used in the industry. There are still two methods to solve the problem. One is improving the stability of SiNPs in ethanol by introducing other functional groups that can react with –COOH groups. Higher stability means higher concentration in the homogenous zone and more deposition particles during short-time EPD process. Another one is using porous Cu foil to increase the contact area between active particles with the substrate.
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